

Faculty of Science and Engineering



APEC 2018 PROFESSIONALEDUCATION SEMINAR

ELECTROMAGNETIC INTERFERENCE & COMPATIBILITY FOR POWER ELECTRONICS ENGINEERS

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OVERVIEW

INTRODUCTION - speaker's background
OVERVIEW OF TUTORIAL

• PART 1 – Context

- Electromagnetic interference & compatibility
- Trends in power systems and power electronics
- Potential impacts of EMI in wireless communication
- EMI Standards

• PART 2 – Fundamentals of EMI

- Power electronics as source of EMI
- Spectral characteristics of switching signals
- Electromagnetic coupling (conduction, induction, radiation)

• PART 3 - Principles and practice of EMI minimisation

- Minimising EMI at the source (e.g. PWM and switching techniques)
- Minimising EMI coupling (e.g. circuit layout, filtering, shielding)
- Measuring EMI





About the presenter...

Graham Town

- Professor, School of Engineering, Macquarie University
- o graham.town@mq.edu.au



Presenter Overview

Graham Town is an electrical engineer with 8 years experience in the Australian electronics industry, and 30 years experience in engineering education and research. He received a Bachelor of Electrical Engineering (Hons1) from NSWIT (now UTS) in 1984, a PhD in medical imaging from the University of Sydney in 1992, and a Graduate Certificate in Leadership and Management (Higher Education) from Macquarie University in 2007.

Graham is currently a Professor in the School of Engineering at Macquarie University where he established Macquarie University's undergraduate engineering program, first offered in 2004. He has published extensively in diverse areas including medical imaging, terahertz technology, guided-wave optics and photonics, and in recent years has been leading industry-supported research on power electronics, and smart-grids with a focus on electric vehicles.

Dr Town is a Senior Member of the IEEE, and a Fellow of Engineers Australia.





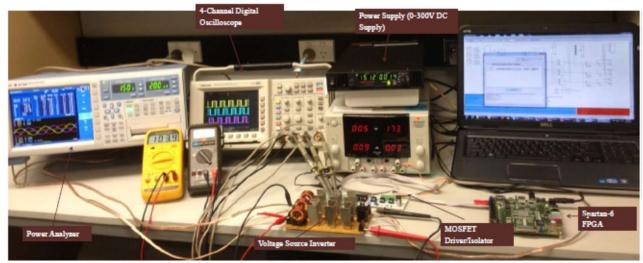
About the presenter

- 1978-81/83/85: Radio Trades Apprentice / Engg Trainee / Engineer
 - AWA Pty Ltd, Industrial Products Division
 - Interscan, μwave comm's, 1st generation optical fibre comm's, etc.
- 1978-84: BE (Hons 1) NSWIT in Electrical Engineering
 - Thesis on holographic antenna measurements, CSIRO Radiophysics
- 1985 1991: PhD Sydney Univ. in Medical Imaging
 - Built 1.5T (64MHz) NMR imaging system
- 1992 2002: Academic Engineer, Sydney Univ.
 - 3rd gen'n optical fibre lasers & guided-wave devices for telecomms and sensing
- 2002 : Academic Engineer, Macquarie Univ.
 - Established BE program at Macquarie Univ. (commenced 2004)
 - Member Sustainable Energy Systems Engineering research group
 - Some externally funded research projects since 2010...
 - Integrated Energy Conversion (GaN power electronics)
 - Distributed Energy Storage and Management (EVs in electrical energy systems)



Integrated Energy Conversion

- **Motivations:** Trend to increasingly compact and portable electronic devices. Increases in energy efficiency \rightarrow savings in infrastructure.
- **Goal:** Electronic power converters with increased efficiency, decreased size.
- **Methods:** GaN devices and circuits, RF switching, novel circuit topologies, intelligent control (e.g. efficient PWM, EMI minimisation, etc).
- **Applications:** Distributed power systems & microgrids (e.g. IT server farms), renewable energy systems, energy-efficient lighting, electric vehicles.



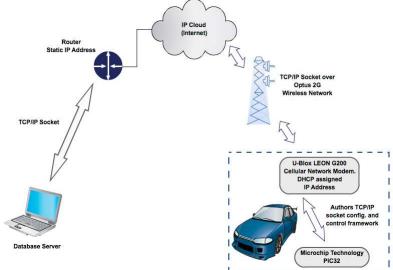
Testing FPGA-controlled switch-mode power supply



Distributed Energy Storage

Motivations:

- ~ 35% of energy in developed countries used for transport
- ~ 20% of vehicles in Australia to be fully or hybrid electric by 2020 [AECOM2012].
- **Goal:** Management electric vehicles and their impact on electric power grids.
- **Methods:** Automatic (M2M) wireless monitoring of vehicle state of charge and position, "smart charging" algorithms for EV batteries, new services for EVs and/or enabled by EVs.
- **Applications:** Future "smart-grid" energy systems incorporating renewable energy and electric vehicles.



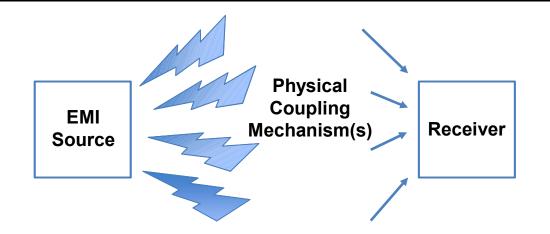
PART 1 - Overview - Aims of this tutorial



- Assist electrical engineers understand \rightarrow apply
 - PART 1 Characteristics of EMI
 - how/why EMI can occur, especially in wireless communication systems
 - potential signs and effects of EMI
 - standards regarding limits and measurements of EMI
 - PART 2 Physical basis of EMI in power electronics
 - switching signals (time $\leftarrow \rightarrow$ frequency)
 - electromagenetics (circuits $\leftarrow \rightarrow$ EM fields)
 - EMI coupling mechanisms (conducted, inducted, radiated) and their dependence upon frequency, distance
 - PART 3 Methods for measuring and minimising EMI
 - by reducing EMI at source
 - by impeding coupling of EMI

EMI and EMC - Definitions





• Electromagnetic Interference (EMI)

"Any electromagnetic disturbance, induced intentionally or unintentionally, that interrupts, obstructs, or otherwise degrades or limits the effective performance of electronics and electrical equipment." *Dictionary of Military and Associated Terms. US Department of Defense 2017.*

The effect of unwanted energy due to one or a combination of emissions, radiations, or inductions upon reception, manifested by any performance degradation, misinterpretation, or loss of information which could be extracted in the absence of such unwanted energy" (*ITU Radio Regulations, Section IV. Radio Stations and Systems – Article 1.166*)

See also https://en.wikipedia.org/wiki/Electromagnetic_interference

Electromagnetic compatibility (EMC)

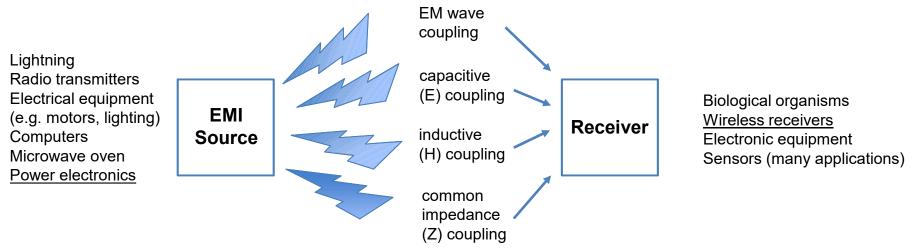
"The ability of systems, equipment, and devices that use the electromagnetic spectrum to operate in their intended environments without causing or suffering unacceptable or unintentional degradation because of electromagnetic radiation or response." *Dictionary of Military and Associated Terms. US Department of Defense 2017.*

See also https://en.wikipedia.org/wiki/Electromagnetic_interference

EMI and EMC - Overview



- Reducing EMI usually improves EMC (reciprocity)
- Options for limiting EMI in any system
 - 1. Reduce interfering emissions from source
 - 2. Impede coupling(s) of interfering emissions
 - 3. Reduce susceptibility of receiver to interfering emissions



The variety of source characteristics and coupling mechanisms can make EMI difficult to diagnose - the effects are often intermittent and remote from the source - but the impacts are potentially serious.

CONTEXT - Types and sources of EMI



• Common types and typical sources of EMI...

- Electrostatic discharge (transient)
 e.g. lightning, failing HV electrical infrastructure, etc.
- Voltage fluctuations and flicker (transient)
 e.g. sudden changes in large and reactive loads, e.g. motors.
- Broadband radio-frequency emissions caused by electrical switching power electronics, motors, etc.
 e.g. "hard" switching in power electronics
- Note: impacts, characterisation methods, standards, and mitigation techniques usually different for different types of EMI

CONTEXT - FOCUS, TRENDS



• This tutorial will focus on EMI...

- caused by power electronics
- in electronic and wireless communication systems...

Motivations...

- trends to increasingly compact and/or efficient power electronics
 - higher switching frequencies, higher speed switching devices (e.g. GaN)

• trends to increasingly pervasive power electronics

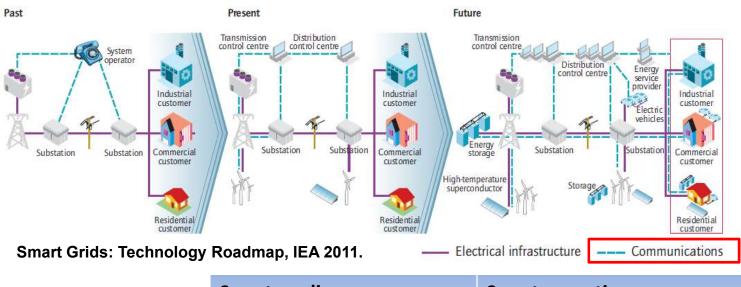
- increased efficiency, control of electrical equipment, e.g. solid state lighting, motors, etc.
- trends to increasing importance of wireless communications in the Internet of Things (IoT) for applications in monitoring and control
 - "smart" grids, microgrids, intelligent transport, etc.
 - emerging low power wide area network standards, use unlicensed (ISM) RF bands, etc.
- trends in EMI regulation and control
 - onus shifting to suppliers to ensure compliance with emission limits.

• costs associated with EMI/EMC minimized if dealt with at the design stage

Background: McHenry, Roberson and Matheson, IEEE Spectrum, August 2015. http://spectrum.ieee.org/telecom/wireless/electronic-noise-is-drowning-out-the-internet-of-things

CONTEXT- Trends in Power Systems





Smart appliances

- Controllable loads
- Status reporting

Smart pricing

• EV as sink/source (V2G)

Value differentiated pricing

Aggregation pricing

Market participation

Smart operations

- Ancillary services
- Reliability
- Service connections
- Firming of renewables

Smart Planning

- Deferral of infrastructure
- Minimise cost
- Minimise carbon

Characteristics and advantages of smart grids

CONTEXT - Trends in Power Electronics



Widebandgap devices - high switching rate and frequency

- \rightarrow increased switching efficiency
- \rightarrow increased power density (smaller reactive components)
- GaN HEMTS can switch very fast (observed):
 - 600 V / 2 ns = 300 kV/us
 - 200 A / 2 ns = 100 kA/us
- Can in turn cause large transient in i & v through parasitic elements:
 - $i_{C} = C. dv/dt$ if C = 10 pF, $i_{Cpk} = 3 A$
 - $v_L = L. di/dt$ if L = 1 nH, $v_{Lpk} = 100 V$

\rightarrow More efficient switching, but more EMI...

- bandwidth (larger d/dt \rightarrow 1000s harmonics, into GHz range)
- transient amplitude (increased peak i_C, v_L in parasitics; C, L)

CONTEXT - Standards, Regulations



Standards and regulations are evolving with technology, policy, etc.

- Power supply efficiency...
 - e.g. US DOE Energy Conservation Standards for External Power Supplies, 2014.
 minimum efficiency typ. > 85%, requires switchmode supplies

• EMI/EMC standards, limits on EMI generation...

- o e.g. European Electromagnetic Compatibility (EMC) Directive 2014/30/EU
- e.g. IEC 61000-3, CISPR 11 15

• EMI/EMC measurement/characterisation methods...

o e.g. IEC 61000-4, CISPR 16, MIL-STD-461

Wireless communication systems...

- e.g. narrowband low power techniques (LTE-NB, etc.)
- o e.g. use of unlicensed (ISM) bands in RF spectrum

Note: See References section for links

CONTEXT - Standards, Regulations



ANSI		
	C63.4	Methods of Measurement of Radio-Noise Emissions from Low-Voltage Electrical and Electronic Equipment in the Range of 9 kHz to 40 GHz
IEC		
	IEC 60050-161	International Electrotechnical Vocabulary. Chapter 161: Electromagnetic compatibility
	IEC 60601-1-2	Medical electrical equipment - Part 1-2: General requirements for basic safety and essential performance - Collateral Standard: Electromagnetic disturbances - Requirements and tests
	IEC 60870-2-1	Telecontrol equipment and systems - Part 2: Operating conditions - Section 1: Power supply and electromagnetic compatibility
	IEC 60940	Guidance information on the application of capacitors, resistors, inductors and complete filter units for electromagnetic interference suppression
	IEC/TR 61000-1-1	Electromagnetic compatibility (EMC) - Part 1: General - Section 1: Application and interpretation of fundamental definitions and terms
	IEC/TS 61000-1-2	Electromagnetic compatibility (EMC) - Part 1-2: General - Methodology for the achievement of the functional safety of electrical and electronic equipment with regard to electromagnetic phenomena IEC/TR 61000-1-6 Electromagnetic compatibility
	IEC/TR 61000-2-1	Electromagnetic compatibility (EMC) - Part 2: Environment - Section 1: Description of the environment - Electromagnetic environment for low-frequency conducted disturbances and signaling in public power supply systems
	IEC 61000-3-8	Electromagnetic compatibility (EMC) - Part 3: Limits - Section 8: Signaling on low-voltage electrical installations - Emission levels, frequency bands and electromagnetic disturbance levels
	IEC/TR 61000-3-15	Electromagnetic compatibility (EMC) - Part 3-15: Limits - Assessment of low frequency electromagnetic immunity and emission requirements for dispersed generation systems in LV network
	IEC TR 61000-4-1	Electromagnetic compatibility (EMC) - Part 4-1: Testing and measurement techniques - Overview of IEC 61000-4 series
	IEC 61000-4-3	Electromagnetic compatibility (EMC) - Part 4-3 : Testing and measurement techniques - Radiated, radio- frequency, electromagnetic field immunity test
	IEC 61000-4-6	Electromagnetic compatibility (EMC) - Part 4-6: Testing and measurement techniques - Immunity to conducted disturbances, induced by radio-frequency fields
	IEC 61000-4-16	Electromagnetic compatibility (EMC) - Part 4-16: Testing and measurement techniques - Test for immunity to conducted, common mode disturbances in the frequency range 0 Hz to 150 kHz
	IEC 61000-4-19	Electromagnetic compatibility (EMC) - Part 4-19: Testing and measurement techniques - Test for immunity to conducted, differential mode disturbances and signalling in the frequency range 2 kHz to 150 kHz at a.c. power ports
	IEC/TR 61000-5-1	Electromagnetic compatibility (EMC) - Part 5: Installation and mitigation guidelines - Section 1: General considerations - Basic EMC publication
	IEC/TR 61000-5-2	Electromagnetic compatibility (EMC) - Part 5: Installation and mitigation guidelines - Section 2: Earthing and cabling
	IEC 61000-6-3	Electromagnetic compatibility (EMC) - Part 6-3: Generic standards - Emission standard for residential, commercial and light-industrial environments
	IEC 61000-6-4	Electromagnetic compatibility (EMC) - Part 6-4: Generic standards - Emission standard for industrial environment
	IEC 61326-1	Electrical equipment for measurement, control and laboratory use – EMC requirements – Part 1: General requirements
	IEC 61326-2-1	Electrical equipment for measurement, control and laboratory use - EMC requirements - Part 2-1: Particular requirements - Test configurations, operational conditions and performance criteria for sensitive test and measurement equipment for EMC unprotected applications
	IEC 61800-3	Adjustable speed electrical power drive systems - Part 3: EMC requirements and specific test methods
	IEC 62040-2	Uninterruptible power systems (UPS) - Part 2: Electromagnetic compatibility EMC) requirements
	IEC 62041	Power transformers, power supply units, reactors and similar products - EMC requirements

CISPR		
	CISPR 11	Industrial, scientific and medical (ISM) radio-frequency equipment - Electromagnetic disturbance characteristics - Limits and methods of measurement
	CISPR 14-1	Electromagnetic compatibility - Requirements for household appliances, electric tools and similar apparatus - Part 1: Emission
	CISPR 15	Limits and methods of measurement of radio disturbance characteristics of electrical lighting and similar equipment
	CISPR 16-1-1	Specification for radio disturbance and immunity measuring apparatus and methods - Part 1- 1: Radio disturbance and immunity measuring apparatus - Measuring apparatus
	CISPR 16-1-2	Specification for radio disturbance and immunity measuring apparatus and methods - Part 1- 2: Radio disturbance and immunity measuring apparatus - Coupling devices for conducted disturbance measurements
	CISPR 16-2-1	Specification for radio disturbance and immunity measuring apparatus and methods - Part 2- 1: Methods of measurement of disturbances and immunity - Conducted disturbance measurements
	CISPR 16-2-3	Specification for radio disturbance and immunity measuring apparatus and methods - Part 2- 3: Methods of measurement of disturbances and immunity - Radiated disturbance measurements
	CISPR 17	Methods of measurement of the suppression characteristics of passive EMC filtering devices
MIL		
	MIL-STD-461	REQUIREMENTS FOR THE CONTROL OF ELECTROMAGNETIC INTERFERENCE CHARACTERISTICS OF SUBSYSTEMS AND EQUIPMENT
	CE101	Conducted Emissions, Power Leads. 30 Hz to 10 kHz
	CE102	Conducted Emissions, Power Leads, 10 kHz to 10 MHz
	CE106	Conducted Emissions, Antenna Terminal, 10 kHz to 40 GHz
	CS101	Conducted Susceptibility, Power Leads, 30 Hz to 150 kHz
	CS103	Conducted Susceptibility, Antenna Port, Intermodulation, 15 kHz to 10 GHz
	CS104	Conducted Susceptibility, Antenna Port, Rejection or Undesired Signals, 30 Hz to 20 GHz
	CS105	Conducted Susceptibility, Antenna Port, Cross-Modulation, 30 Hz to 20 GHz
	CS109	Conducted Susceptibility, Structure Current, 60 Hz to 100 kHz
	CS114	Conducted Susceptibility, Bulk Cable Injection, 10 kHz to 200 MHz
	CS115	Conducted Susceptibility, Bulk Cable Injection, Impulse Excitation
	CS116	Conducted Susceptibility, Damped Sinusoidal Transients, Cable and Power Leads, 10 kHz to 100 MHz
	RE101	Radiated Emissions, Magnetic Field, 30 Hz to 100 kHz
	RE102	Radiated Emissions, Electric Field, 10 kHz to 18 GHz
	RE103	Radiated Emissions, Antenna Spurious and Harmonic Outputs, 10 kHz to 40 GHz
	RS101	Radiated Susceptibility, Magnetic Field, 30 Hz to 100 kHz
	RS103	Radiated Susceptibility, Electric Field, 2 MHz to 40 GHz RS105 Radiated Susceptibility, Transient Electromagnetic Field

See also https://en.wikipedia.org/wiki/List_of_common_EMC_test_standards

CONTEXT - Standards, Regulations



• EMI/EMC Standards may in general be grouped by

- EM emissions vs susceptibility to interference (Tx vs Rx)
- EM coupling mode and/or frequency (conducted, inducted, radiated)
- Measurement method (depending on i and ii)

or by

- Equipment function (e.g. power supply, communication)
- Equipment application (e.g. commercial, medical, military)

BACKGROUND- Digital Communication Systems

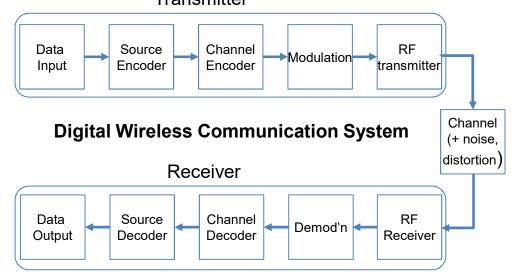
The main functional blocks in a digital wireless communication system are as follows...

- Source Encoding/Decoding Compresses the input data to remove any redundant or unneeded information. For analogue source signals, source coding performs an analogue to digital conversion. Decoding reverses the process.
- **Channel Encoding/Decoding** Channel encoding adds some redundancy to minimize the effects of fading and noise in the channel.
- Modulation/Demodulation

The bit stream is modulated to generate the transmitted signal, e.g. pulse modulation at baseband, amplitude and/or phase modulation of RF carrier.

Transmission/ Reception

Amplification and transduction to/from propagating radio waves. May also involve i) multiplexing for multiple access, ii) mixing to intermediate frequencies (IF). Transmitter



MACQUARIE University

BACKGROUND - Potential Impacts of EMI



Susceptibility to interference depends on system design...

- coding
- modulation
- RF carrier frequency, etc.

linked to system requirements...

- data rate
- range (sensitivity)
- multiple access methods
- EM environment
- mobility, etc.

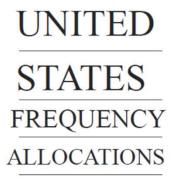
and system application...

- simple wireless point-to-point links (e.g. remote control)
- low power communications (sensing , IoT)
- cellular mobile phone networks (4G \rightarrow 5G), etc.

BACKGROUND - Radio Frequency Spectrum

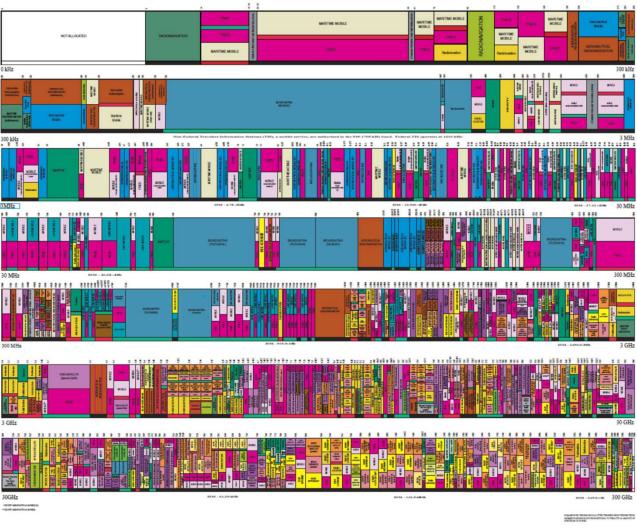


19



THE RADIO SPECTRUM





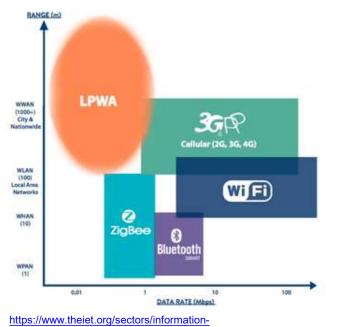
BACKGROUND . Wireless communication standards

- Many wireless systems and standards for various communications applications (voice, IoT, etc.)....
- Can be classified by...
 - Range (m to many km)
 - o Data rate
 - System complexity
 - License arrangements for use of RF spectrum

• Examples of wireless communication systems...

- WiFi (802.11n)
- 2G/3G/4G/5G (cellular mobile phone networks, 0.9 2.1, 5 GHz)
- ISM (Industrial, Scientific, Medical) unlicensed 900MHz, 2.4GHz, etc.
 - Bluetooth, Zigbee (2.4GHz ISM)
- LPWAN (low power wide area networking), IoT
 - LTE NB (cellular, licensed), LoRa, Sigfox (ISM)

BACKGROUND MACQUARIE - Low-power wide-area network standards



communications/topics/ubiquitous-computing/articles/lpwan.cfm

	LORA-WAN	SigFox	NB-IoT	CATM1	RPMA
Modulation	DSS with chirp	UNB/ GFSK/ BPSK	OFDMA/ SC-FDMA	OFDMA/ SC-FDMA	RPMA
Frequency	868/ 902- 928MHz	868/915 MHz	In band LTE, guard band and stand alone	In band LTE	2.4GHz
Coverage	153-161 dB	149-161 dB	164dB	155.7dB	168-172dB
Bandwidth	125kHz	100Hz (EU)	180kHz	1.08MHz	1MHz
Data rate	0.3 to 50 kbps	100bps	50kbps	1Mbps	624 Kbps DL
Data fate					156 Kbps UL
Max msg /	unlimited	140 UL	n/a	unlimited	n/a
day		4 DL			, u

BACKGROUND - Narrow-band wireless for IoT



	LTE Cat 1	LTE Cat 0	LTE Cat M1 (eMTC)	LTE Cat NB1 (NB-IoT)
3GPP Release	Release 8	Release 12	Release 13	Release 13
Downlink Peak Rate	10 Mbit/s	1 Mbit/s	1 Mbit/s	250 kbit/s
Liplink Doak Pato	5 Mbit/s	1 Mbit/s	1 Mbit/s	250 kbit/s (multi- tone)
Uplink Peak Rate				20 kbit/s (single- tone)
Latency	50-100ms	not deployed	10ms-15ms	1.6s-10s
Number of Antennas	2	1	1	1
Duplex Mode	Full Duplex	Full or Half Duplex	Full or Half Duplex	Half Duplex
Device Receive Bandwidth	1.08 - 18 MHz	1.08 - 18 MHz	1.08 MHz	180 kHz
Receiver Chains	<u>2 (MIMO)</u>	<u>1 (SISO)</u>	1 (SISO)	1 (SISO)
Device Transmit Power	23 dBm	23 dBm	20 / 23 dBm	20 / 23 dBm

https://en.wikipedia.org/wiki/NarrowBand_IOT

BACKGROUND - Wireless comunication

RF carrier modulation

Analogue (continuous) modulation

- Amplitude modulation
- Frequency/phase modulation
- Hybrids

Digital (quantized, discrete) modulation

- o ASK
- o FSK
- o PSK
- Hybrids (e.g. QAM) -

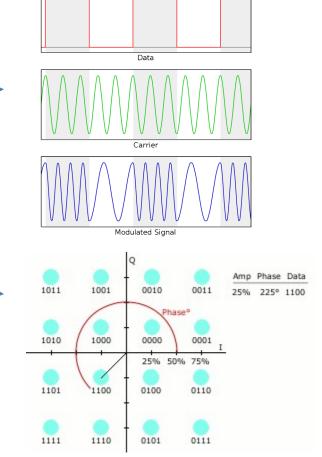
Spread spectrum methods

- Time/Frequency hopping/diversity
- Direct sequence spread spectrum
- o OFDM

Demodulator designed to distinguish between points in signal constellaion







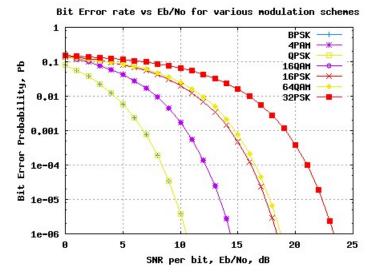
BACKGROUND - Potential Impacts of EMI



- EMI usually regarded as noise in wireless comms.
- Effects of noise (interference) depend upon
 - 1. Modulation method
 - Analogue modulation
 - AM: severe interference, noise = "signal" (e.g. AM radio near computer)
 - F/PM: through nonlinear effects, e.g. overloading of receiver
 - Digital modulation
 - Effects of interference generally less obvious, up to a threshold

2. Noise (interference) power relative to signal power

- NOTE: "Knee" in BER characteristic...
- \rightarrow BER deteriorates rapidly with SNR



https://www.embedded.com/print/4017668

BACKGROUND - Examples of EMI and impact



- Interference between automotobile ignition system and car radio. Taggart, Methods of suppressing automotive interference, NBS Special Publication 480-44, 1981. <u>http://nvlpubs.nist.gov/nistpubs/Legacy/SP/nbsspecialpublication480-44.pdf</u>
- Satellite deployment failure due to inductive coupling (crosstalk) between an unshielded attitude control sensor cable and the power bus of the spacecraft. (The control systems cable was redesigned and shielding added).

Leach et al (NASA), Electronic systems failures and anomalies attributed to electromagnetic interference, NASA-RP-1374, 1995. <u>https://ntrs.nasa.gov/archive/nasa/casi.ntrs.nasa.gov/19960009442.pdf</u>

• Misoperation of neighbour's garage door opener when LED lighting with dimmer turned on. (Dimmer removed).

McHenry, Roberson and Matheson, Electronic Noise is drowning out the Internet of Things, IEEE Spectrum, August 2015. <u>http://spectrum.ieee.org/telecom/wireless/electronic-noise-is-drowning-out-the-internet-of-things</u>

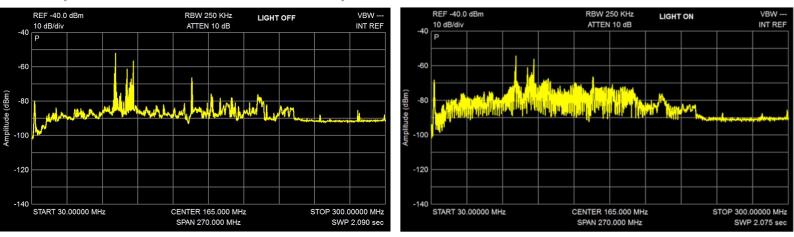
BACKGROUND - Examples of EMI

5W MR16 LED Downlight Review

General Information

ID	#154
SKU	LTMR5W3K2P
Series	N/A
Manufacturer	Click (other LEDs from Click)
Fitting Type	MR16 (other MR16 LEDs)
Light Type	Downlight (PAR)
Height	48mm
Diameter	PAR16 (50mm)
Weight	42g







http://www.ledbenchmark.com/faq/LED-interference-issues.html

START 30.00000 MHz

REF -40.0 dBm

10 dB/div

-40

-60

-100

-120

-140

(dBm 80

Amplitude

http://www.ledbenchmark.com/faq/LED-interference-issues.html

27

BACKGROUND - Examples of EMI

5W MR16 Downlight Review

General Information

ID	#131
SKU	LMR16BL27538
Series	N/A
Manufacturer	Mirabella (other LEDs from Mirabella)
Fitting Type	MR16 (other MR16 LEDs)
Light Type	Downlight (PAR)
Height	50mm
Diameter	PAR16 (50mm)
Weight	47g

RBW 250 KHz

ATTEN 10 dB

CENTER 165.000 MHz

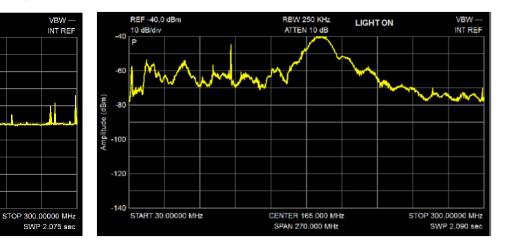
SPAN 270.000 MHz

and the state of the

LIGHT OFF









PART 2 – Overview - EMI Fundamentals



o EMI Fundamentals

- i) generation
- ii) coupling (energy transfer)
- Foundations: signals in linear systems

i) Signals - two perspectives: time domain ←→ frequency domain
 ii) Systems - two perspectives: electric circuits ←→ electromagnetic fields
 All perspectives are consistent wrt energy in both time and space.

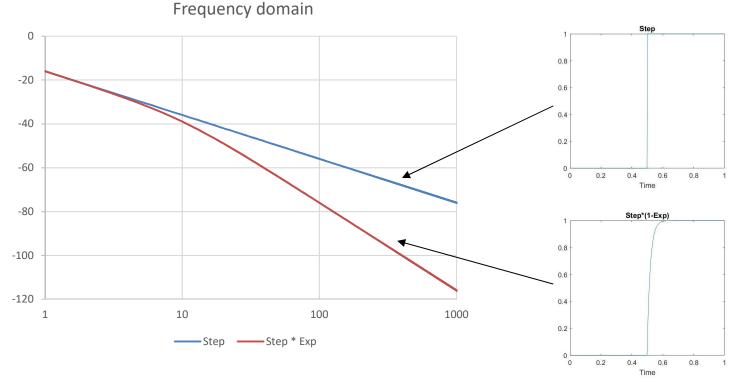
 Understanding, from an appropriate perspective, how electrical and magnetic energies are <u>embodied</u>, <u>connected</u>, and <u>interact with their environment</u>

 \rightarrow effective EMI minimisation and mitigation strategies

Fundamentals of EMI - Signals



- Every switch transition generates di/dt, dv/dt → EMI spectrum
 F{sgn(t)} = -j/ω
- ~ ns rise time (GaN) \rightarrow EMI cutoff frequency ~ 350 MHz



Fundamentals of EMI - Signals



Additional material to be included

Spectrum of a pulse Spectrum of a periodic train of pulses

Fundamentals of EMI - Electric Circuits



- Differences in electric potential (voltage) drive electrical currents around circuits, transporting electrical energy from source to load.
- Energy *dissipated* in resistive components:
 R = v_R/i_R (resistance, R [Ω] = electric potential [V] per unit current [A])
- Energy stored in reactive components: $v_L(t) = L.di_L/dt, \mathcal{E}_L = \frac{1}{2}L.i^2$ (inductance L [H] = magnetic flux linkage Λ [Wb] per unit current i [A]) $i_C(t) = C.dv_C/dt, \mathcal{E}_C = \frac{1}{2}C.v^2$ (capacitance C [F] = electric flux (or charge) ψ [C] per unit voltage v [V]) Reactance (sinusoidal steady state): $X_L(\omega) = \omega.L, X_C(\omega) = -(\omega.C)^{-1}$ (reactance $X(\omega)$ [Ω] = $|V(\omega)/I(\omega)|$) Impedance (sinusoidal steady state): Z = R + jX (complex impedance $Z(\omega) = V(\omega)/I(\omega)$ [Ω])
- Power flow (= rate of energy change) Instantaneous: w(t) = v(t).i(t) Sinusoidal steady state: Complex power: $S(\omega) = V(\omega).I^*(\omega) = P + jQ$ [W] Real or active power: $P = \Re_e \{S\} = S.cos(\theta)$ [W] Reactive power: $Q = \Re_m \{S\} = S.sin(\theta)$ [VAR] Apparent power: $S = |S| = (P^2 + Q^2)^{\frac{1}{2}}$ [VA] Power factor: $f = P/S = cos(\theta)$ By Wikieditor4321 (Own work) [CC BY-SA 4.0 (https://creativecommons.org/licenses/by-sa/4.0))
- Maximum real power flow from source to load when Sinusoidal steady state: $Z_{LD}(\omega) = R_{LD} + j X_{LD}(\omega) = R_S - j X_S(\omega) = Z_S^*(\omega)$ [NB: when $R_{LD} = R_S, X_{LD} = -X_S$]
- Also, waves on transmission lines (distributed circuit; t & d, two conductors)

Fundamentals of EMI - Electromagnetic Fields



- Energy density at a point in space, **r**, associated with
 - electric fields **E** [V/m] and associated electric flux density **D** = ε . **E** [C/m] $\mathcal{E}_{E}(\mathbf{r}) = \frac{1}{2} \varepsilon E^{2} [J/m^{3}]$, (permittivity $\varepsilon = \varepsilon_{r} \cdot \varepsilon_{0}$, permittivity of free space $\varepsilon_{0} = 8.85 \times 10^{-12} [F/m]$)
 - magnetic fields **H** [A/m] and associated magnetic flux density **B** = μ .**H** [Wb/m] $\mathcal{E}_{H}(\mathbf{r}) = \frac{1}{2} \mu H^{2} [J/m^{3}]$, (permeability $\mu = \mu_{r}$. μ_{0} , permeability of free space $\mu_{0} = 4\pi \times 10^{-7} [H/m]$)
 - Changes in E can induce H, and vice versa, even in free space.
 - As for circuits, we may define complex impedance $Z_z(\mathbf{r}, \omega) = E_x(\mathbf{r}, \omega)/H_y(\mathbf{r}, \omega)$ [Ω] Note: Orthogonal components of **E** and **H** used. For sinusoidal steady state (at frequency ω), the real (in phase) and imaginary (phase-quadrature) parts related to energy dissipation and storage, respectively.
- Power flow (= rate and direction of energy density change at a point in space) Poynting theorem: P(r,t) = E(r,t) x H(r,t) [W/m²] Sinusoidal steady state: P_{av}(r,ω) + jQ_{av}(r,ω) = ½ E_{pk}(r) x H*_{pk}(r) [W/m²]
- Also, wave phenomena in free space (and in waveguides; t & r, single conductor)

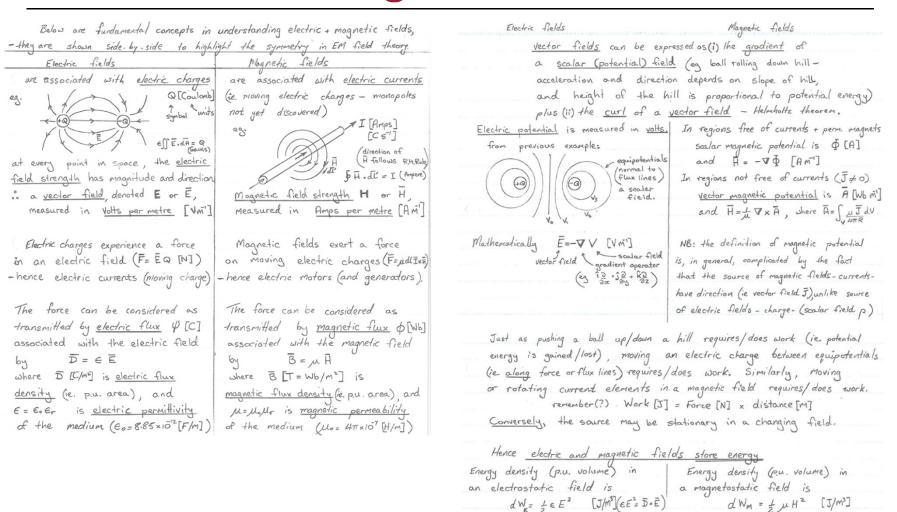
NOTE: Field and circuit models consistent - linked by considering energy:

- Voltage difference between two points in space \rightarrow electric field.
- Moving charge (current) through space \rightarrow magnetic field.
- Energy stored in static (d/dt = 0) electric and magnetic fields consistent with lumped circuit model
- o Electromagnetic wave phenomena in transmission lines consistent with distributed circuit model

Exception: electromagnetic wave propagation in free space – changing E and H linked by Maxwell, who predicted

EM waves before experimental observation - but concept of impedance and other wave phenomena still apply.

Fundamentals of EMI - Static electromagnetic fields



Total energy stored Total energy stored $W_E = \frac{e}{2} \int_{U} E^2 dv$ (volume integral) Wm = M (H2du [J]

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Fundamentals of EMI - Electromagnetics of circuits



Lumped circuit elements (static or slowly-varying fields) A Capacitor is a circuit element An Inductor is a circuit element which stores energy in an electric field which stores energy in a magnetic in the space between two conductors field in the space around a current-carrying wire. 000000 - E 1 defined by $C = \frac{Q}{V} [C/V = F]$ (charge p.u. volt) $L = \lambda [Wb/A = H]$ defined by eq. If area of plates is S, and (if no) separation is d, B. dA $W_{E} = \frac{1}{2} \int_{U} e E^{2} dU \qquad \left(E = \frac{V}{d} \right)$ (flux linkage p.u. curi eg. For long solenoid of N turns $= \frac{1}{2} \in (\frac{V}{d})^2$. Sd @@@@@@@@ $B \xrightarrow{\text{Wellow}} H \xrightarrow{\text{Hold}} H$ $We = \frac{1}{2} \left(e \frac{S}{2} \right)^{1/2} = \frac{1}{2} C V^{2}$ = = QV [J] where $C \doteq \in S$ [F](ignoring fringe fields) To change the voltage on the capacitor = 2 M (NI)2. Al means a change in electric field, : • $W_{M} = \frac{1}{2} (\mu N^{2} A) I^{2} = \frac{1}{2} L I^{2} [J]$ and a change in stored charge where L= UN2A [H] (reakage and I end-effects) (ie current against electric potential = WORK) now Q= [Idt = CV [C] I= C dV [A] To change the current flowing in 00 the inductor requires a change in from cct. theory, Nork done in (WE = [VI dt []] stored magnetic flux charging capacitor $= C \int V dV = \frac{1}{2} C V^2$ e = - dx/dt (by Faraday) V=-e, V=+LdI [V] Hence circuit theory and From cct. field theory agree on energy theory, work done & Wm = (VIdt in increasing current { stored in a lumped circuit element. =+L (IdI =+1 LI2

SCHOOL OF ENGINEERING

LOSSLESS TRANSMISSION LINES time-damain analysis agent is bon cable Transmission lines (composed of 2 or more conductors) are useful for transporting electromagnetic energy over a wide range of frequencies (DC - GHZ). [M5: waveguides, composed of single conductors or dielectrics, perform a similar function, but have a minimum usable frequency. Waveguides util be studied in the 2nd half of this course] Hithough the conocidance and inductance of 2-conductor eystems can be calculated, for any given length of line, (from electrostatic and magnetostatic theory), how do we model the line? Except at very low ^{DC} thequencies, when fields may be considered as "static", nerther is correct - we must consider the capacitance and inductance to be distributed along the length of the transmission line. So VIND Loss the speak of C [F/m], L [H/m]. This approch stats with field theory (statics), but uses circuit theory analysis. power 50 HZ 6000 kn When soavelength is telephone 3 kHz 100 kn comparable to size of FM (Flyndio) 100 MHZ 3 m circuit theory books down (Fwyhly, C.T. requires 0-16 x > z) 34	I CITCUILS	
source ribbon cable Transmission lines (composed of 2 or more conductors) are useful for transporting electromagnetic energy over a wide range of frequencies (2C-GHZ). [NB: waveguides, composed of single conductors or dielectrics, perform a similar function, but have a minimum usable frequency. Waveguides will be studied in the 2nd half of this course] Although the conscitance and inductance of 2-conductor systems can be calculated, for any given length of line, (from electrostatic and magnetostatic theory), how do we model the line? Except at very low threquencies, when fields may be considered as "solatic", neither is correct - we must consider the conscitance and inductance to be distributed along the length of the transmission line. So $\frac{2ax_2}{caz}$ $\frac{cax_2}{caz}$ • the smaller bz, the better the model. • For linear geometry, we speak of C [F/m], L [H/m]. This approch starts with field theory (statics), but uses circuit theory analysis. power So Hz book m When uswelle to size of FM (Fyredio) no MHz 3 m Unerd element (is line length) µWwe Io GHz 3 cm circuit theory broks down		
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whave 10 GHZ 3 cm circuit theory breaks down		
uWave 10 GHz 3 cm circuit theory breaks down (roughly, C.T. requires 0-12 > z) 34		
	Wave 10 GHZ 3 cm circuit theory breaks down (roughly, C.T. requires 0-12 > 2)	34

34

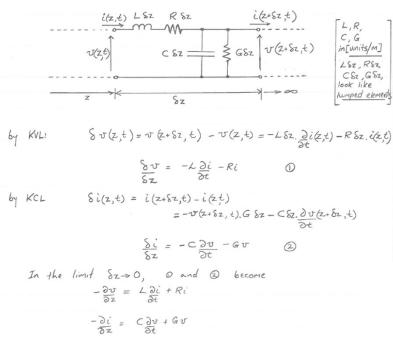
Fundamentals of EMI MACQUARIE University - Electromagnetics of distributed circuits

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66	6/6/
+	A I
da	Í
Simplify geome	try - ignore end effects
51	
E E	
surface of conductors are	Approximate analysis
equipotentials, and may be	flux linking one conductor with other
considered due to two line-charges.	$\Phi = \int_{\frac{1}{2\pi r}} \frac{\mu I}{2\pi r} dr = \frac{\mu I}{2\pi} \ln\left(\frac{d-a}{a}\right) \left[\frac{Wb}{m}\right]$
Calculating potential as function	from H for single conductor.
of position (ref Cheng p146-147	Total inductance is
RWD p23), for each conductor,	$L \neq 2. \Phi = \mu \ln(d-1) [H/m]$
and adding, we obtain	
$C = \frac{\pi \epsilon}{\cosh^2(d_{1/2\alpha})} [F/m]$	It can be shown exactly (RWD p185)
cooh"(d/2a)	that
	L= # cooh-1 (d/20) [H/M]
If in a medium with finite	
conductivity,	The series resistance depends on
$G = \frac{\pi \sigma}{\cosh^{-1}(d/2a)} [S/m]$	skin effect, which causes current
cosh-i (d/za)	to flow near the surface of
NB conduction current flows along E,	conductors at high frequencies.
so J has same form as D,	from Chang p387, RWD p182,
hence similar expressions for	
	$R = \frac{1}{a} \sqrt{\frac{f\mu}{\pi\pi}} \left[\frac{f\alpha}{m} \right]$

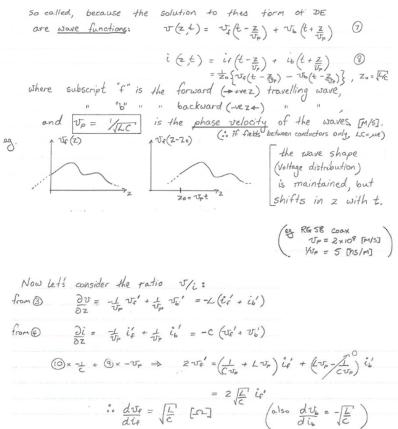
Calculation of typical transp electrostatics BE = 0 Simplify geometry-	rission line parameters - Cashal ringuelostatics <u>BB</u> = 0 I I ignore and effects V
E Capacitance defined by	F. Taking a lina integral over a
C=Q/V [F] where	circular path between the conductors
+ Q is distributed evenly over surface	I= find = H& 2TT
inner conductor, and -Q is	$B_{\phi} = \mu H_{\phi} = \mu I_{\frac{2\pi r}{2\pi r}}$
distributed evenly over inner surface	
of outer conductor.	$\phi_{\phi=} \int_{a}^{b} B dr \left[\frac{Wb/m}{2\pi} - \frac{WI}{2\pi} \ln(\frac{b}{a}) \right]$
Taking a cylindrical surface about the inner conductor with radius $a < t < b$ $\iint_{C} D \cdot d\overline{R} = +Q$	$L = \frac{\phi}{T} = \frac{\mu}{2\pi} \ln(b/a) \left[\frac{H}{M} \right]$ H audio trequencies and lower,
$\int_{S} E_{r} \cdot 2\pi r \cdot \ell = Q$	the flux inside the centre conductor
E= Q der arrab	May be considered $H_{\phi} = \int_{-\infty}^{\infty} J = \frac{I}{\pi a^{2}} \left(A / M^{2} \right)$
The voltage between inner and	-an Current enclosed by path
outer conductor surfaces is	with radius $\tau < a$, $I(\tau) = J. \pi \tau^2$ [A]
$V = \int_{-\infty}^{\infty} E_r dr$	$= I \left(\sqrt{a} \right)^{2}$
- 0 [k/m]76	: I(r) = & H. d. = Hg. 2n+
$= \frac{Q}{2\pi\epsilon} \left[\ln(\epsilon) \right]_{\alpha}^{b}$	$ \overset{\circ}{}_{\circ\circ} H \phi = \underbrace{I.(r/a)}_{2\pi r}^{2} = \underbrace{I}_{2\pi a^{3}} r $
= $\frac{Q}{2\pi e} ln(b/a)$ [V]	Flue in ring rods linking with Itr)
	dof= uH+ dr = UwI. + dr
substitution gives	$L_{\mu} = \int_{\frac{\pi}{2}}^{\frac{\pi}{2}} d\phi = \int_{\frac{\pi}{2}}^{\frac{\pi}{2}} (\frac{\pi}{2})^{k} \cdot \frac{\mu \tau}{2\pi n^{k}} dr$
substitution gives $C = Q/V = \frac{Q}{\frac{Q}{2\pi e L}} (b/A)$	$\begin{split} d\phi &= \sum_{\mu} H_{\phi} d\sigma = \sum_{\substack{Z = \pi + 1 \\ Z = \pi + 1 \\ J_{\mu} = 1}} \frac{1}{f(\sigma)} d\phi = \int_{\sigma}^{T} (\frac{1}{2\pi})^{1} \cdot \frac{\mu + \tau}{2\pi\pi} d\tau \\ & \vdots L_{\nu} = \sum_{\substack{M = \nu \\ S = \tau}} \frac{1}{f(\sigma)} \int_{\sigma}^{T} (\frac{1}{2\pi})^{1} \int_{\sigma}^{M} d\sigma = \frac{1}{2\pi} \int_{\sigma}^{M} (b_{A}) d\sigma \\ & = \int_{\sigma}^{T} \frac{1}{2\pi} \int_{\sigma}^{T} (\frac{1}{2\pi})^{1} \int_{\sigma}^{M} d\sigma = \int_{\sigma}^{M} (b_{A}) \int_{\sigma}^{M} (b_{A}) d\sigma \\ & = \int_{\sigma}^{M} \frac{1}{2\pi} \int_{\sigma}^{M} (b_{A}) \int_{\sigma}^{M} \frac{1}{2\pi} \int_{\sigma}^{M} (b_{A}) \int_{\sigma}^{M} \frac{1}{2\pi} \int_{\sigma}^{M} \int_{\sigma}^{M} \frac{1}{2\pi} \int_{\sigma}^{M} \int_{\sigma}^{M} \frac{1}{2\pi} \int_{\sigma}^{M} \int_{\sigma}^{M} \frac{1}{2\pi} \int_{\sigma}^{M} \int_{\sigma}^{M} \int_{\sigma}^{M} \frac{1}{2\pi} \int_{\sigma}^{M} \int_{\sigma}^{M} \int_{\sigma}^{M} \frac{1}{2\pi} \int_{\sigma}^{M} \int_$
2 mel [F]	
$=\frac{2\pi\epsilon l}{ln(b/a)}$	
$ie C = \frac{2\pi e}{\ln(b/a)} [F/m]$	

eg. RG58 coax : C= 100 [pF/m] a=0.45 MM Er= 2.28 , M=1 b= 1.5 mm "€= 1.95×10"[F/m L= 240 [nH/m]

Fundamentals of EMI - Waves on transmission lines



In many cases, the losses due to R and G can be neglected. This simplifies analysis for Non-sinusoidal dignals, so $\begin{array}{rcl} \partial v &= -\lambda \ \partial i \\ \partial z &= -c \ \partial v \\ \partial z &= -c \ \partial$



 $\frac{di_{f}}{\sqrt{c}} = \frac{di_{h}}{\sqrt{c}} = \frac{di_{h}}{$

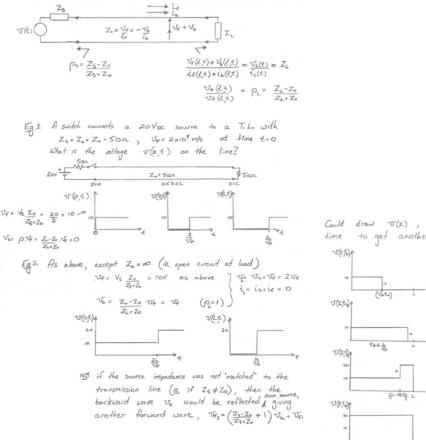
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Fundamentals of EM waves - Reflections on transmission lines

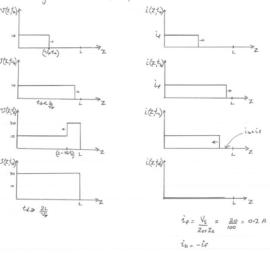
MACQUARIE University

The question now arises - what happens on a finite length T.L. when the forward travelling wave comes to the end of the line (ie. the load)? Basically, this is a boundary value problem the load impedance ZL constrains the v/i ratio at the end of the line. i) If ZL=Zo, then the load looks like an infinitely long transmission line (of the same characteristic impedance) and no reflections occur. 2) If Zit Zo, then Vilit + Vile and a reflected wave is set up so that the total voltage and current waves satisfy Vf + V6 = ZL The forward and backward waves are still defined by V7 = - V6 = Zo $\frac{v_{f+}v_{b}}{z_{o}} = \frac{z_{c}}{z_{o}}$ Therefore . Alternatively, the magnitude of the reflected wave relative to the incident wave is: - ib = Z1-Zo p is defined as the reflection coefficient

 $\begin{bmatrix} NB & p may be complex, implying magnitude and phase differences in the reflected wave, if Z_L complex. If Z_L=Z₀, <math>p=0$, is no reflection occurs.



Could draw v(z), t(z) at various instants in time to get another perspective:



Fundamentals of EM waves Acquarie University - Sinusoidal waves on transmission lines

We will now derive the above using phasors, include the effect of losses. now $U(z,t) = Re\left\{V(z) e^{i\omega t}\right\}$ $i(z,t) = Re\left\{I(z) e^{i\omega t}\right\}$	and O 2
and the Telegrapher's Eqns, with loss, are	
$-\frac{\partial v}{\partial z} = R_i + L \frac{\partial i}{\partial t}$	3
$-\frac{\partial i}{\partial z} = Gv + C\frac{\partial v}{\partial t}$	
$\frac{\partial^2 V(z)}{\partial z^2} = + \left(\mathcal{R}_{ij} \omega L \right) \left(\mathcal{G}_{ij} \omega \mathcal{C} \right), \forall (z) = \delta^2 $	
$\frac{\partial^{2} I(z)}{\partial z^{2}} = + (G_{+j}\omega C)(R_{+j}\omega L), I(z) = \chi^{2} I(z)$	(z) (§)
(1) and (1) may easily be solved, to give	
$ \Lambda(z) = \Lambda^{t}(z) + \Lambda^{p}(z) = \Lambda^{to} \mathcal{C}_{\chi z} + \Lambda^{po} \mathcal{C}_{\chi z} $ $ \Lambda(z) = \Lambda^{t}(z) + \Lambda^{p}(z) = \Lambda^{to} \mathcal{C}_{\chi z} + \Lambda^{po} \mathcal{C}_{\chi z} $	(9) (10)
Here \forall is called the <u>propagation constant</u> where $\forall = \infty + j\beta = \sqrt{(R_+;\omega L)(G_+;\omega C)}$ $\frac{attenuation}{Constant} = \frac{constant}{Constant}$ [Ne/m] [Fad/m]	(1)
$\beta = \omega_{AT_p}$ (how fast phase changes) $\left[\frac{4/5}{M/5}\right] = \left[\frac{4^{-1}}{M}\right]$ (spatial frameword)	
The characteristic impedance is defined, as befo	re, by
$Z_{0} = \frac{V_{f}}{I_{f}} = -\frac{V_{b}}{I_{b}} = \sqrt{\frac{R+j\omega L}{G+j\omega C}} \left[\Omega\right] \left(for a lossless \\ Z_{0} = \sqrt{\frac{L}{C}}\right)$	
where R,G,L,C, are again in [Units/metre.]	(12)

Example

A	telephone	Line	is measured	at 1kz, and found to
have	R=	4.2	sz/km	G= 0.2 us/km
	∠ =	2.2	mH/km	C = 5.4 nF/km

Given $v(o,t) = cos(\omega t)$, if frequency is 1kHz, calculate characteristic impedance, attenuation, and delay at a point 10km along the line. Also write both the time domain and phasor formulae for voltage + current there.

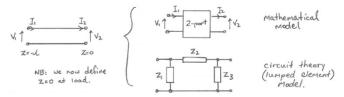
$$\begin{split} \text{Soh:} & \omega = 2\pi f = 2\pi \times 10^{5} \, \text{[f/s]} \\ \text{from (i2), } Z_{\bullet} \left(1 \, \text{kHz} \right) = \sqrt{\frac{4 \cdot 2 + j \times 2\pi \times 10^{3} \times 2 \cdot 2 \times 10^{-3}}{0 \cdot 2 \times 10^{-6} + j \times 2\pi \times 10^{5} \times 5 \cdot 4 \times 10^{-9}}} = \sqrt{\frac{4 \cdot 2 + j \cdot ./3 \cdot 8}{0 \cdot 2 \times 10^{-6} + j \cdot 3 \cdot 4 \times 10^{-7}}} \\ & \vdots Z_{\circ} \left(1 \, \text{kHz} \right) = \sqrt{\left(4 \cdot 2 + j \cdot .3 \cdot 8 \right) \left(0 \cdot 2 \times 10^{-6} + j \cdot 3 \cdot 4 \times 10^{-7} \right)} = \sqrt{\frac{2 \cdot 0 \cdot 2 \times 10^{-6} + j \cdot 3 \cdot 4 \times 10^{-7}}{0 \cdot 2 \times 10^{-6} + j \cdot 3 \cdot 4 \times 10^{-7}}} \\ & \text{from (i)} \quad & \forall \left(1 \, \text{kHz} \right) = \sqrt{\left(\frac{4 \cdot 2 + j \cdot .3 \cdot 8}{0 \cdot 2 \times 10^{-6} + j \cdot 3 \cdot 4 \times 10^{-7} \right)} = \sqrt{\frac{2 \cdot 0 \cdot 47 + j \cdot 0 \cdot 15 \times 10^{-31}}{0 \cdot 2 \times 10^{-6} + j \cdot 3 \cdot 4 \times 10^{-7}}} \\ & \text{from (i)} \quad & \forall \left(1 \, \text{kHz} \right) = \sqrt{\left(\frac{4 \cdot 2 + j \cdot .3 \cdot 8}{0 \cdot 2 \times 10^{-6} + j \cdot 3 \cdot 4 \times 10^{-7} \right)} = \sqrt{\frac{2 \cdot 0 \cdot 47 + j \cdot 0 \cdot 15 \times 10^{-31}}{0 \cdot 2 \times 10^{-5} \times 10^{-31}}} \\ & \text{from (i)} \quad & \forall \left(1 \, \text{kHz} \right) = \sqrt{\left(\frac{4 \cdot 2 + j \cdot .3 \cdot 8}{0 \cdot 2 \times 10^{-6} + j \cdot 3 \cdot 4 \times 10^{-5} \right)} = \sqrt{\frac{2 \cdot 0 \cdot 47 + j \cdot 0 \cdot 15 \times 10^{-31}}{0 \cdot 2 \times 10^{-5} \times 10^{-31}}} \\ & \text{from (i)} \quad & \forall \left(1 \, \text{kHz} \right) = 0 \cdot 0 \cdot 0 \cdot 33 \left[N p / \, \text{km} \right] \\ & \text{is} \quad & \propto \left(1 \, \text{kHz} \right) = 0 \cdot 0 \cdot 22 \left[\, \text{frod} / \, \text{km} \right] \\ & \text{is} \quad & \propto \left(1 \, \text{kHz} \right) = 0 \cdot 0 \cdot 22 \left[\, \text{frod} / \, \text{km} \right] \\ & \text{is} \quad & \propto \left(1 \, \text{kHz} \right) = 0 \cdot 0 \cdot 22 \left[\, \text{frod} / \, \text{km} \right] \\ & \text{is} \quad & \approx \left(1 \, \text{kHz} \right) = 0 \cdot 0 \cdot 22 \left[\, \text{frod} / \, \text{km} \right] \\ & \text{is} \quad & \approx \left(1 \, \text{kHz} \right) = 0 \cdot 0 \cdot 23 \left[\, \text{km} \right] \\ & \text{is} \quad & \text{is$$

Fundamentals of EM waves - Impedance transformations



We are often only interested in what hoppens at the terminals (ie input + output) of a transmission line, rather than what goes on in between (which is usually inaccessible anyway).

In such situations, it is useful to have a model for the transmission line



Using these models we will see how transmission lines can be used for <u>impedance</u> transformation, and how they can be used as <u>lumped elements</u>, at any <u>one frequency</u>.

2-Port model

In general, any circuit with an input and output can be modelled as a 2-port network 2 described by parameters (usually frequency dependent) which relate the input + output voltages + currents,

For transmission lines, transmission parameters are best $\begin{bmatrix} V_1 \\ I_1 \end{bmatrix} = \begin{bmatrix} A & B \\ C & D \end{bmatrix} \begin{bmatrix} V_2 \\ I_2 \end{bmatrix} \qquad (4)$ $i/P \qquad \text{xmission} \qquad 0/P$ matrix

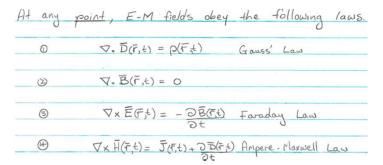
1	back towards the source, the total urrent at $z = -L$ is $V_1 = V_4 e^{KL} + V_6 e^{KL}$		- Uz
	$I_{1} = \frac{V_{f}}{Z_{o}} e^{\xi \ell} - \frac{V_{b}}{Z_{o}} e^{\xi \ell} - \frac{V_{b}}{Z_{o}} e^{\xi \ell}$	Z=-L	Z10
Solving	(B) and (B) for Vf and Vb , and su $V_f = \frac{1}{2}(V_2 + Z_0 I_2)$	ubst. into (7) ar	(B)
	$V_{b} = \frac{1}{2} (V_{2} - Z_{0} I_{2})$		
		= V2 ceoh 8l + Z	To Iz sinh X
	$V_{\rm b} = \frac{1}{2} \left(V_2 - Z_0 I_2 \right)$		

Using the mathematical model we can calculate the
impedance seen looking in to the transmission line
at any point, given a load
$$Z_L$$

Impedance seen at $z = -d$ is:
from (P)
(2) $Z_{in} = \frac{V_1}{I_1} = \frac{AV_2 + BV_2/Z_L}{CV_2 + DV_2/Z_L} = Z_0 (\frac{Z_L \cosh M + Z_0 \sinh M'_1}{Z_L \sinh M'_1 + Z_0 \cosh M'_1})$
(4)
Heratively equations (D) + (13) could be written using $\rho = \frac{V_0}{V_4} = (Z_L - Z_0)/(Z_L + Z_0)$
 $I_1 = \frac{V_1}{Z_0} e^{2K} (1 + \rho e^{2K})$ so $Z_{in} = Z_0 (\frac{1 + \rho e^{-2K}}{I - \rho e^{-2K}})$
(2)
The load impedance Z_i is transformed to look like Z_in by T-L.

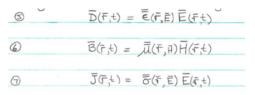


- Maxwells equations (point or differential form)
 - Describe how EM fields vary about a point in space, r



Constitutive equations

o Describe the medium in which the fields exist



Note: in general, all variables

- are vectors they have direction and magnitude
- represent fields distributed throughout space, function of r

Fundamentals of EMI - Electromagnetic fields and waves

All engineering electromagnetic phenomena can be described by solving the partial differential equations 1 - 4, subject to

i) constitutive equations 5-7, and

ii) boundary conditions (depend on physical layout, to be specified).

Solutions of Maxwell's equations predict to a high degree of accuracy phenomena such as

- Electromagnetic coupling in and between "lumped" electrical circuits
- Behaviour of distributed electrical circuits (dimensions comparable to λ)
- Electromagnetic wave propagation and interaction with materials
- Transduction between circuits and EM waves (antennas)
- Guidance of EM waves
- EM waves in free space

Fundamentals of EMI - Electromagnetic fields and waves



Symbols [units]

- A vector which denotes position F [m, radians] in space relative to some reference point. The coordinate system used may be any one of the orthogonal coordinate systems (rectangular, cylindrical, spherical, etc) but should be chosen to use symmetries present in the boundary conditions. [C.m-2] Electric flux density, a vector field. D is (at any instant in time) the flux density may have a unique direction and magnitude at every point in space. [C.m⁻³] Charge density, a scalar field. ie (at any instant in time) the charge density may have a unique magnitude at every
- point in space. (density closs not have direction)

Ē	[V.m] Electric field strength, a vector field.
B	[T= Wb.m2] Magnetic flux density, a vector field
A	[Am'] Magnetic field strength, a vector field.
Ī	[A.M2] Current density, a vector field
\bigtriangledown	gradient operator "del", a vector operator
	eg in 3D rectilinear coordinates $\nabla = i \frac{2}{2} + j \frac{2}{2} + k \frac{2}{2}$
	where I, J, k are unit vectors in the
	x, y, z directions, respectively.
	The gradient of a scalar function (eg. $\nabla \phi$)
	(at any point) is a vector which points
	in the direction of greatest change of Ø
	(eq if $\phi(\overline{r})$ represents the elevation of a hill as
	a function of position, then a ball placed at F
	on the hill will voll in the direction of $-\nabla \Phi$).

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Meaning of symbols, vector operators

$\nabla \cdot \overline{F} \text{ divergence}, \text{ scalar product of gradient and vector field}$ eq in 3D rectilinear coordinates $\overline{\nabla \cdot F} = (\overline{x} \underbrace{2} + \overline{y} \underbrace{2} + \overline{z} \underbrace{2} \underbrace{2} \\ \xrightarrow{\nabla x} + \underbrace{2F_2} \underbrace{2} \underbrace{2} \underbrace{2F_x} + \underbrace{2F_z} \\ = \underbrace{2F_x} + \underbrace{2F_y} + \underbrace{2F_z} \\ \xrightarrow{\partial x} & \underbrace{2} \underbrace{2} \\ \xrightarrow{\partial x} & \underbrace{2} \underbrace{2} \\ \xrightarrow{\partial x} & \underbrace{2} \\ \xrightarrow{\partial y} & \underbrace{2} \\ \xrightarrow{\partial z} \\ \xrightarrow{\partial z} & \underbrace{2} \\ \xrightarrow{\partial z} \\ \partial $	$\nabla \times \vec{F} \text{ curl}, \text{ vector product of gradient and vector field.}$ eg in 3D rectilinear coordinates $\nabla \times \vec{F} = \begin{vmatrix} \vec{x} & \vec{y} & \vec{z} \\ = \vec{x} (\underbrace{\Im}_{S} F_{z} - \underbrace{\Im}_{S} F_{z}) + \vec{y} (\underbrace{\Im}_{S} F_{z} - \underbrace{\Im}_{S} F_{z}) + \vec{z} (\widehat{\Im}_{S} F_{z} - \underbrace{\Im}_{S} F_{z}) + \vec{z} (\widehat{\Im}_{S} F_{z} - \underbrace{\Im}_{S} F_{z}) + \vec{z} (\widehat{\Im}_{S} F_{z} - \underbrace{\Im}_{S} F_{z}} + \vec{z} (\widehat{\Im}_{S} F_{z}) + \vec{z} (\widehat$
SCHOOL OF ENGINEERING	$\nabla x F \neq 0$ eq water flow over eq magnetic flux a surface $a \text{ surface} \qquad around a \text{ constant line current}$ $\frac{\text{Stokes theorem velates the line integral of field}}{\text{around a closed contour } to the total curl of}$ the field over any surface enclosed by the contour. $(O) \qquad \qquad$



Special situations leading to simplification of equations

D M	axwell's equations
-	static fields
6)	sinusoidal (time-harmonic) fields
c)	charge free, current free regions.
1a)	if the EM fields depend only on position, that is
	they are "static" in time, eqns () to (2) become
	$\nabla . \overline{D} = \rho \nabla \times \overline{E} = 0$
	$\nabla \cdot \vec{B} = 0$ $\nabla \times \vec{H} = \vec{J}$
(stu	idents should be familiar with static electric and magnetic fields)
6)	if the EM fields vary sinusoidally in time (in a stationary frame) is $\vec{E}(\vec{r},t) = Re\left\{ \hat{\vec{E}}(\vec{r},t), e^{j\omega t} \right\}$ $\vec{B}(\vec{r},t) = Re\left\{ \hat{\vec{B}}(\vec{r}), e^{j\omega t} \right\}$ $\vec{B}(\vec{r},t) = Re\left\{ \hat{\vec{B}}(\vec{r}), e^{j\omega t} \right\}$
	$\overline{B}(\overline{r},t) = Re \left\{ \widehat{B}(\overline{r}) e^{j\omega t} \right\} \rho(\overline{r},t) = Re \left\{ \widehat{\rho}(\overline{r}) e^{j\omega t} \right\}$
	equations () to () may be written
	$\nabla \cdot \hat{D} = \hat{\rho} \nabla \times \hat{E} = -j\omega \hat{B}$
	$\nabla \cdot \hat{B} = O \nabla \times \hat{H} = \hat{J} + j \omega \hat{D}$
+	hese are the complex, time harmonic form of Maxwell's eqns.
	in a charge free region $p(F,t) = 0$
	in a region free of conduction current $\overline{J}(\overline{r},t)=0$
	in free space, both (i) and (ii) are true so,
-	V.D=O VXE=-DB/2t
	V.B=O V×H= DA/Ot
6	note the symmetry of Maxwell's eqn's in free space)

- 2) Constitutive equations
- a) isotropic media
- b) homogeneous media
- c) linear media

	A medium is <u>isotropic</u> if it has the same property in all directions (is scalar), then equs.
	() and for () and for () become
	B and for () and for () become
	$(a) = \overline{J(F,t)} = \sigma(F,E) \overline{E}(F,t)$
	Anisotropic media are used in devices such
	as light polarisers and circulators, however
	as ught polarisers and circulators, nowever
	we won't be studying such devices in this
	course, so from now on totally isotropic media
	will be assumed. (It is rare that more than one
	of e, u, or be anistropic in any case)
6)	A medium is homogeneous if it has the same
	property at all points (ie independent of F).
	Therefore for homogeneous and isotropic media
	equations Sa and/or Ba and/or Da become
	\mathfrak{D}_{b} $\overline{\mathfrak{D}}(\bar{r}, \mathfrak{k}) = E(E) \overline{E}(\bar{r}, \mathfrak{k})$
	$ \begin{array}{ccc} & & & & & \\ & & & \\ & & & \\ \hline \\ \hline$
	Ideal media are generally regarded as homogeneous
	unless the inhomogeneity is purposefully controlled
	(eg by modifying a homogeneous material with
	the inclusion of material with different properties)
	An example of an inhomogeneous medium is the ionosphere
	All media considered in this course will be homogeneous.
c)	
	of the opplied field (is constant wrt. E= E , H= H)
	Equations Oband/or Ob and/or Ob become
	D(Et) - E E E(Et) / D = E E)
	$\overline{B}(\overline{r}, t) = \mathcal{M}_{O}\mathcal{M}_{\Gamma} \overline{H}(\overline{r}, t) \qquad \overline{B} = \mathcal{M}_{\overline{H}}$ $\overline{J}(\overline{r}, t) = \mathcal{M}_{\overline{F}}(\overline{r}, t) \qquad \overline{J} = \mathcal{M}_{\overline{F}}$
	$\overline{T}(\overline{z},t) = \sigma \overline{F}(\overline{z},t)$ $\overline{T} = \sigma \overline{F}$



Integral form of Maxwell's equations

- o describe EM field properties over regions, action at a distance
- o btained by integrating differential equations, using fundamental properties of vector fields → Gauss' Law, Faraday's Law

D and Q give $\oint \overline{D} \cdot d\overline{S} = \int \nabla \cdot \overline{D} dV = \int_{V} \rho dV = Q$ divergence thm. Maxwell.	B) and (i) give $emf = \oint_{\mathcal{L}} \overline{E} \cdot d\overline{L} = \int_{S} \nabla x \overline{E} \cdot d\overline{S} = -\frac{2}{2t} \int_{S} \overline{B} \cdot d\overline{S} = -\frac{2\Phi}{2t}$ Solves thm. Maxwell
$ \begin{array}{cccc} \bigcirc $	
Similarly @ and @ give @a & B.ds = 0 = Qm ie. the total magnetic flux leaving a closed surface is zero. OR magnetic flux always links with itself	$\frac{F_{oraday'_{S}} L_{aus}}{by} \forall = \oint \overline{E}, d\overline{L} = -\frac{2}{2t} \iint_{S} \overline{B} \cdot d\overline{S} = -\frac{2\phi}{2t} \qquad \qquad$
<u>Gouss' Law</u> $\Psi = \iint_{S} \overline{D} \cdot d\overline{S} = \iint_{V} \rho dV = Q$ (charge = flux) by divergence theorem $\iint_{S} \overline{D} \cdot d\overline{S} = \iint_{V} \nabla \cdot \overline{D} dV$ equating terms inside the volume integrals $\nabla \cdot \overline{D} = \rho$ Similarly, for magnetic fields, $\iint_{S} \overline{B} \cdot d\overline{S} = 0$, \therefore $\nabla \cdot \overline{S} = 0$	equating terms inside the surface integrals $\nabla x \overline{E} = -\frac{\partial \overline{E}}{\partial t}$ Similarly, for <u>Amperes Las</u>



Integral form of Maxwell's equations

describe EM field properties over regions, instead of at points \rightarrow Ampere's Law

(4) and (2) give $mmf = \int \overline{H} \cdot d\overline{L} = \int \nabla x\overline{H} \cdot d\overline{S} = \int (\overline{J} + \partial \overline{D}) \cdot d\overline{S} = (\sigma + \varepsilon \partial) \int_{\overline{S}} \overline{\varepsilon} \cdot d\overline{S}$ $= I_{\varepsilon} + \varepsilon \partial f_{\varepsilon}$ $= I_{\varepsilon} + I_{D} = I_{tot}$ (4) $mmf = \oint \overline{H} \cdot d\overline{L} = I_{tot}$ $= I_{c} + I_{D} = I_{tot}$ (4) $mmf = \oint \overline{H} \cdot d\overline{L} = I_{tot}$ $= I_{tot} Amperes \ Low$ This says that the magnetomotive force around a loop L equals the current linking L . Maxwell modified Ampere's law by adding a 'displacement'' component of current $(\overline{J}_{D} = \partial \overline{D})$, so $= \partial f D D D D D D D D D $	More symbols: E [Fm ¹] Electric permittivity (U [Hm ¹] Magnetic permeability (Um ¹] Electric conductivity (Um ¹] Electric conductivity (IC] Electric flux [C] Electric flux [C] Electric current due to flow of electric charge [D][A] Displacement current due to change in electric flux. Q[C] Electric charge Qm [Wb] Magnetic charge (non existent, by @a) X, Y, Z unit vectors in x, y and z directions. (Note: the dependence of quantities on time and or space is often onitted for brevity, don't let this confuse you!)
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Fundamentals of EMI - Sinusoidal electromagnetic waves

	= medium be linear, homogeneous + isotropic
	Then
	$\nabla x \overline{E} = - \overline{\partial} \overline{B} = - u \overline{\partial} \overline{H}$
	Dt Dt
	$\nabla \times \overline{H} = \overline{J} + \partial \overline{D} = \sigma \overline{E} + \epsilon \partial \overline{E}$
	94 94
	$\nabla \times \nabla \times \overline{E} = -\mu \partial(\nabla \times \overline{H}) = -\mu \sigma \partial \overline{E} - \mu \varepsilon \partial^{2} \overline{E}$
	$\nabla(\nabla, \bar{E}) - \nabla^2 \bar{E} = -\mu\sigma \partial \bar{E} - \mu\epsilon \partial^2 \bar{E} \\ \partial t = \partial t$
00	$\nabla^2 \overline{E} - \mu \sigma \partial \overline{E} - \mu \varepsilon \partial^2 \overline{E} = \nabla \rho \varepsilon = 0 \mathbb{O}^*$
	* Let p=0 (eg. in free space, homogeneous conductors)
	then in 3D rectilinear coordinates () is
	$\frac{\partial^2 E_x}{\partial x^2} + \frac{\partial^2 E_x}{\partial y^2} + \frac{\partial^2 E_x}{\partial z^2} = \frac{\mu_0}{\partial t} \frac{\partial E_x}{\partial t} + \frac{\mu_0}{\partial t} \frac{\partial^2 E_x}{\partial t}$
	$\frac{\partial^2 E_y}{\partial x^2} + \frac{\partial^2 E_y}{\partial z^2} + \frac{\partial^2 E_y}{\partial z^2} = \mu\sigma \frac{\partial E_y}{\partial t} + \mu\epsilon \frac{\partial^2 E_y}{\partial t^2} \qquad \bigcirc o$
	$\frac{\partial^2 E_z}{\partial x^2} + \frac{\partial E_z}{\partial y^2} + \frac{\partial E_z}{\partial z^2} = \mathcal{M}\sigma \frac{\partial E_z}{\partial t} + \mathcal{M}\varepsilon \frac{\partial^2 E_z}{\partial t^2}$
	Similar relations hold for the components of A
VB :	D=O was assumed implicitly in using Ohm's Law, J=OE, tather than
(charge continuity, $\nabla \cdot \overline{J} = -\partial p_{St}$, in deriving eqn 2.
. 2	$\nabla \cdot \nabla \times \vec{H} = 0 = \nabla \cdot (\vec{\sigma} + \epsilon \partial_{\partial t}) \vec{E} = (\sigma_1 \epsilon \partial_{\partial t}) \nabla \cdot \vec{D} = (\sigma_1 \epsilon \partial_{\partial t}) \cdot \rho_{\ell} \vec{E}$

wave	ing the fields vary sinusoidally " in time, the Helmholtz eqns become (time - harmonic form)
	$\nabla^2 \hat{E}(\bar{F}) = +j \omega \mu (\sigma + j \omega \epsilon) \hat{E}(\bar{F}) \qquad (0 \ \alpha$
	$\nabla^2 \hat{H}(\vec{r}) = +j\omega\mu(\sigma + j\omega \in) \hat{H}(\vec{r})$ (2) a
*(NB	in linear media, E-M waves with non-sinusoidal and
	non-periodic time-variation can be synthesised by position of waves with appropriate frequencies + amplifudes)
Also	for simplicity, let $\hat{E}(\bar{r}) = \bar{x} E_x(\bar{r}) (ie the (electric) field is timearly polarised \\ in the x \cdot direction, so E_y = E_z = 0) (ex endowned the \\ event verticed verti$
	1) $E(\bar{r}) = \bar{x} E_x(\bar{r})$ (ie the (electric) field is linearly polarised
	in the x-direction, so $E_y = E_z = 0$ (as included up to the polarization) can
	then since $\nabla x \hat{E} = -j \omega \mu \hat{H}$ superposition
	Z DEX - Z DEXIWHA (HX=0)
	d let Dz Dy
an	$\overline{\varphi} \frac{\partial E_x}{\partial z} - \overline{z} \frac{\partial E_x}{\partial y} = -j\omega\mu \hat{H} \qquad (H_x=0)$ d let 2) $\hat{H}(F) = \overline{\varphi}H_y(F)$ (ie $H_z=0$ also, this leads to one TEM
	2) HUT = Y HUT (IE HZ=O also, This reads to the IEM
	- wave travelling in the z-direction)
	$\frac{1}{2} \qquad \qquad$
1	
	also from $\nabla x \hat{H} = (\sigma_{+j} \omega \epsilon) \hat{\epsilon}$, $\frac{\partial H_y}{\partial x} = 0$, and from $\nabla \cdot \hat{B} = 0$, $\frac{\partial H_{y=c}}{\partial y} = z \frac{\partial H_y}{\partial z} - x \frac{\partial H_y}{\partial z}$ $\hat{o} \in \mathbb{Z}$ and Hy only vary in the z-direction
	= Z Hy - Z Hy
	as E- and Hy only vary in the z-direction
Under	assumptions (1) and (2) above, the wave equations Da, Ja become
	$\frac{\partial^2 E_x}{\partial z^2} - \delta^2 E_x = 0, \frac{\partial^2 H_y}{\partial z^2} - \delta^2 H_y = 0 \text{(b)} = 0$
	∂z^2 ∂z^2

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Fundamentals of EMI - Sinusoidal electromagnetic waves

By the usual methods, or by inspection, the solution to equation Ob is,

 $E_{x} = E_{x}^{+} e^{\forall x} + E_{x}^{-} e^{\forall x}$ $so \quad \overline{E} = \overline{x} \operatorname{Re} \left\{ E_{x}^{+} e^{i\omega(t+j\underline{x})} + E_{x}^{-} e^{i\omega(t+j\underline{x})} \right\}$ $= \operatorname{Re} \left\{ \widehat{E}(z) e^{i\omega t} \right\}$ which you should recognise as the sum of a forwards
and backwards travelling wave. (since <math>x complex, in general,
the wave may be attenuating as it propagates).
Once \overline{E} is known, \overline{H} follows by (or vice versa) $\widehat{H} = j \underbrace{\Box}_{uju} (\nabla \times \widehat{E})$ $\vdots \quad H_{y} = -i \underbrace{x}_{x} (E_{x}^{+} e^{\underline{x}z} - E_{x}^{-} e^{\underline{x}z}) \quad where \quad \underline{E}_{x}^{+} = -\underline{E}_{x}^{-} = j \underbrace{\omega \mu}_{x} = \eta$

 $\begin{array}{cccc} & & & & & & \\ & & & & & \\ & & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & \\ & & & \\$

It has thus been shown that a possible solution of the Helmholtz equations is a wave, travelling in a linear, homogeneous and isotropic medium without boundaries such that the E field and A field are everywhere perpendicular to each other and to the direction of propagation (given by ExA).

Y = x + jB	propagation constant of	the medium.
	mation constant of the m	
	e constant of the medium	
	intrinsic impedance of -	
$\omega/\beta = c$	velocity of wave in the	e medium [ms].
	wavelength of wave in	

) In free space o=0, u=10, E=E.
and the forward travelling Erlwave is $\vec{E} = \vec{x} \cdot E_{\vec{x}} \cdot e^{-jty \cdot \vec{x}}$
NO: \vec{E}, \vec{H} in phase $\vec{F} = \vec{x} E_x^* \cos[\omega(t - \mu E_x^*)] = \vec{x} E_x^* \cos(\omega t - \beta z)$ if η real $\vec{H} = \vec{\gamma} E_x^* / \cos[\omega(t - \mu E_x^*)] = \vec{\gamma} E_x^* \cos(\omega t - \beta z)$
$(H = \overline{\gamma} E_{x/n} \cos[\omega(t - \sqrt{l_0} \epsilon_0 z)] = \overline{\gamma} E_{x} \cos(\omega t - \beta z)$
In free space, EM waves travel at
$C_o = \frac{1}{\sqrt{u_o \epsilon_o}} = 3 \times 10^8 \text{ [ms]]}$
and the intrinsic impedance of free space is $\eta = \sqrt{\frac{1}{E_0}} = 377 rad$
2) In good conductors, conduction current dominates over displacement current so $\sigma \gg \omega \varepsilon$
$\delta = \sqrt{\frac{\omega}{\omega}} = \sqrt{\frac{\omega}{\omega}} = \sqrt{\frac{\omega}{\omega}} = \frac{\omega}{\omega} + \frac{\omega}{\omega}$
and the forward travelling E wave is (A similar but with phase shift)
$\overline{E} = \overline{x} E_{x}^{+} \exp\left(-\int \frac{\omega \mu \sigma'}{2} z\right) \cos\left[\omega \left(t - \int \frac{\mu \sigma'}{2} z\right)\right]$
$= \times L_{\infty} \mathcal{L}$ ($\omega L - \beta \mathcal{L}$)
The phase velocity is $c = \sqrt{\frac{2\omega}{\mu\sigma}} [MS^{1}]$
and intrivisic impedance $\eta = j \omega \mu = (1+j) \sqrt{\omega \mu} [\Omega]$
The skin depth is a measure of depth to which the
E-M wave travels into the conductor
$S = \frac{1}{\alpha c} = \sqrt{\frac{2}{\omega \mu \sigma}} [m] \qquad \qquad \left(E_o e^{-\alpha \delta} = E(\delta) = \frac{E_o}{e} \right)$



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Fundamentals of EMI - Boundary conditions

BETWEEN MEDIA WITH DIFFERENT INTRINSIC	
IMPEDANCES, THEN IN ORDER FOR THE FIEL	10.6
	-DS
AT THE INTERFACE TO SATISFY BOUNDARY	
CONDITIONS, A REFLECTED WAVE AND TRANSP	AITTED
WAVE MAY RESULT	
(FINALOGIES:) REFLECTIONS ON TRANSMISSION LINES	FROM
UNMATCHED SOLACES OR LOADS ZL #	
2) NON - MAXIMUM POWER TRANSFER IN	I CIRUITS
WITH LOAD UNMATCHED TO SOURCE	ZL #Zs*
HOWEVER, THESE ANALOGIES ARE ONLY GOOD WHEN	
CONSIDERING FLANE WAVES NORMALLY INCIDENT	AT
PLANE INTERFACES. WAVES CAN ALSO MEET IN	TERFACES
OBLIQUELY).	
1	

WHEN A WAVE ENCOUNTERS A BOUNDARY

REVIEW OF BOUNDARY CONDITIONS
Basically tangential components of E and H
(or, alternatively, normal components of D and E)
(or, alternatively, normal components of \overline{D} and \overline{E}) must be continuous across the boundary.
D TANGENTIAL E DOEL NOT CHANGE AT BOUNDARIES
$E_{41} \bigcap f = \frac{1}{2} \int \overline{E} \cdot d\overline{l} = \frac{1}{2} \int \overline{E} \cdot d\overline{s} \implies 0 as S \rightarrow 0$ $\therefore E_{41} \supset L = 0$
$\vdots E_{4}, \Delta L = E_{42} \Delta L = 0$
\vdots \vdots $E_{t_1} = E_{t_2}$ [ie. $\overline{n} \times (\overline{E}_1 - \overline{E}_2) = 0$]
NB if one of the media is a perfect
conductor, then $E_{t_1} = E_{t_2} = 0$ [ie. $\overline{n} \times \overline{E} = 0$]

2) TANGENTIAL A DOES NOT CHANGE AT BOUNDARIES (a surface current) Using same setup as in (1),					
$\oint_{\mathcal{D}} \vec{H} \cdot d\vec{L} = \oint_{\mathcal{D}} (\vec{J} + 2\vec{D}) \cdot d\vec{S} \implies O \qquad a \qquad \delta \rightarrow O \text{if } \lim_{\substack{D \neq O \\ D \neq O}} J, D = O$ (it J, D finite)					
$\stackrel{\circ}{\underset{\circ}{\circ}} H_{4_1} = H_{4_2} \qquad [ie. \overline{n} \times (\overline{H}_1 - \overline{H}_2) = \bigcirc]$					
However, in a perfect conductor (eg superconductor)					
all internal magnetic fields are zero due to					
surface currents. In that case $\lim_{s \to 0} J = J_s (Am^i)$ if $H_{4_2} = O$, $H_{4_1} = J_s$ [if $\overline{N} \times \overline{H}_1 = \overline{J}_s$]					
3) NORMAL D DOES NOT CHANGE AT BOUNDARIES (a surface charge)					
$\int_{a}^{D_{ni}} \oint_{a} \overline{D} \cdot d\overline{s} = \int_{V} p dV \implies O \text{ as } S \Rightarrow O \text{ if } p \text{ finite}(\lim_{s \to 0} p = 0)$					
$D_{n_1} dS_1 - D_{n_2} dS_2 = 0$					
$D_{n_1} = D_{n_2} \left[ie \ \overline{n} \cdot (\overline{D}_1 - \overline{D}_2) = O \right]$					
However, in a perfect conductor charge resides only at the surface ($\lim_{\delta \neq 0} \rho = \rho_{\delta} [Cm^{3}]$) then $D_{2,\epsilon}O_{\delta}$, $D_{m}=\rho_{\delta}$ [ie $\overline{n}, \overline{D}_{\delta} = \rho_{\delta}$]					
4) NORMAL B DOES NOT CHANGE AT BOUNDARIES					
Using some setup as (3) $ \oint_{S} \overline{B} \cdot d\overline{S} = 0 $ $ \stackrel{\bullet}{\bullet} B_{n1} = B_{n2} \left[ie. \ \overline{n} \cdot (\overline{B}_{1} - \overline{B}_{2}) = 0\right] $ In a superconductor, $B_{n1} = B_{n2} = 0 \left[ie. \ \overline{n} \cdot \overline{B} = 0\right]$					
SUMMARY OF BOUNDARY CONDITIONS					
$\sigma = finite = \infty$					
(c) $\overline{n} \times (\overline{E}_1 - \overline{E}_2) = O$ (dugential E) $\overline{n} \times \overline{E} = O$					
(BC) $\overline{n} \cdot (\overline{B}_1 - \overline{B}_2) = O$ (normal B) $\overline{n} \cdot \overline{B} = O$					
(B) $\overline{n} \times (\overline{H}_1 - \overline{H}_2) = 0$, $\forall J = 0$, $\forall J = \overline{n} \times \overline{H}_1 = \overline{J}_5$ [Am]					

 $\overline{n} \cdot (\overline{D}_1 - \overline{D}_2) = 0$, or $p_s \cdot f p \rightarrow \infty$ $\overline{n} \cdot \overline{D}_1 = p_s$

BCY



[Cm2]

Fundamentals of EMI - Reflections of plane waves



Fundamentals of shielding against EMI in far field Assumption: plane wave normally incident on plane boundary between two semi-infinite regions

- (TEM incidence)
- Analogous to reflections of waves on transmission lines (also TEM) Ο

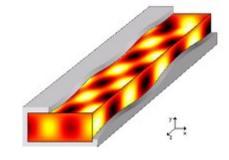
Fundamentals of EMI - EM waves - summary

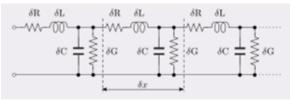


- EM waves in free space (EM radiation)
 - o antenna = V \leftarrow →E, I \leftarrow → H "transducer"
- Guided EM waves
 - TEM (two conductors \rightarrow transmission line; V, I)
 - TE, TM (one conductor, dielectric \rightarrow waveguide; E,H)

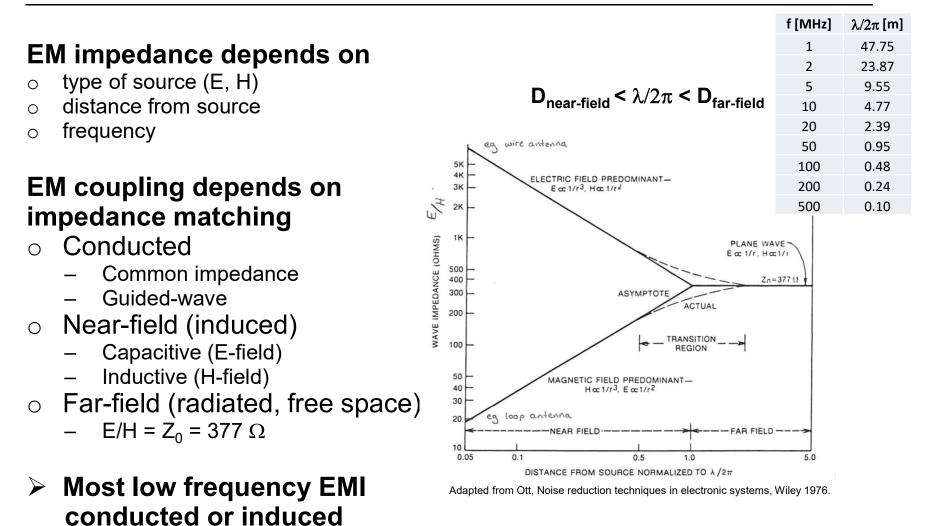
• For all waves, two fundamental parameters:

- Wave impedance, Z(z) = E_x(z)/H_y(z) = V(z)/I(z)
 real part → energy dissipation
 imaginary part → energy storage
- Propagation constant, $\gamma = \alpha + j\beta = j\omega\mu.(\sigma + j\omega\varepsilon)^{\frac{1}{2}} = j\omega\mu/Z$
 - $\alpha \boldsymbol{\rightarrow}$ change in amplitude with distance loss, evanescent fields
 - $\beta \not \rightarrow$ change in phase with distance propagating fields
- $\circ \quad Z = j \omega \mu / \gamma$





Fundamentals of EMI - EM wave impedance, near vs far field



PART 3 – Overview- EMI reduction strategies



- Modulate PWM parameter(s) e.g. switch phase (or frequency)
 - spreads EMI over more frequencies...
 - ...reduces peak power spectral spectral density (no change to average PSD)
- "Soft" switching of active devices generate fewer harmonics
 - resonant converters limit number of harmonics
 - slow switching reduce di/dt, dv/dt limit bandwidth of harmonics
 - additional circuitry, complexity, loss

2. Reduce EMI coupling, impede energy transfer

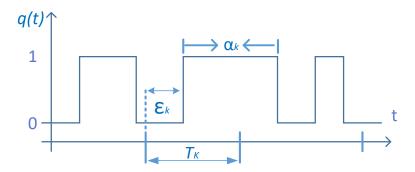
- Circuit layout (conducted, induced)
- Filtering (conducted, induced)
 - cost & size
- Shielding (induced, radiated EMI)
 - weight + cost
 - often need to allow for ventilation



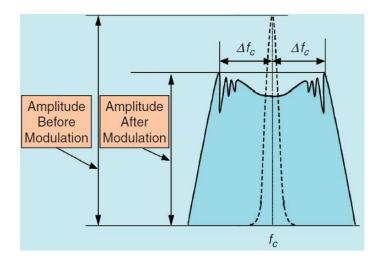
Reduce EMI Generation - PWM techniques



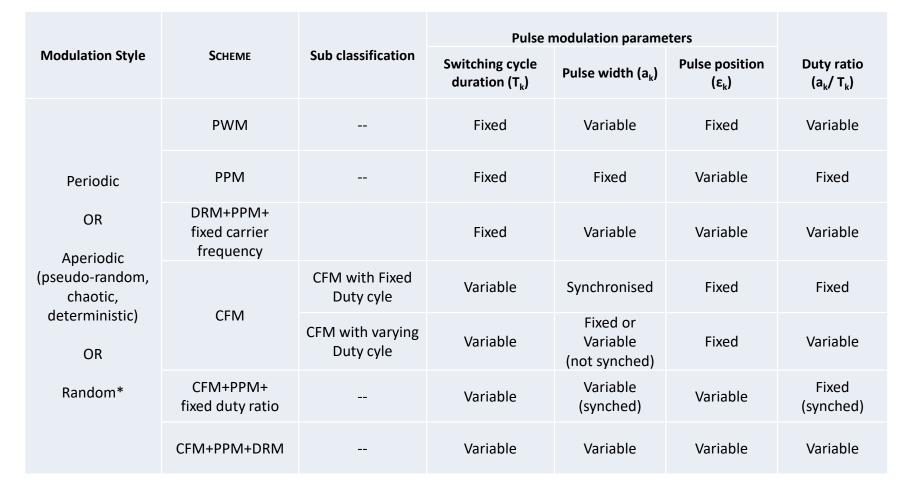
Modulating one or more parameters of a switch driving signal, q(t)



redistributes energy in frequency domain



Reduce EMI Generation - Classification of PWM techniques



PWM= Pulse Width Modulation, PPM= Pulse Position Modulation, DRM= Duty Ratio Modulation, CFM= Carrier Frequency Modulation

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Reduce EMI Generation - PWM techniques



Additional material to be included

Example of PWM technique for EMI mitigation "Soft" Switching

EMI Reduction MACQUARIE - Minimising common impedance coupling

3	Common impedance coupling.
	This doesn't involve coupling of electric or magnetic fields via
	non-conductive media, but coupling between circuits which
	have some conductive part in common. The most common
	such situation arises in "grounding" different parts of a
	circuit.
	Currents through circuit 2
	T Cet Cet Cet at to earth raise the "earth"
	potential seen by ccts 1 and 2.
	= 1 Real problems occur if, for example,
	small but finite impedances circuit 1 is sensitive analog city, and in earth return Z=R+jwLs
	in earth return Z=R+jWLs Zor 3 are digital circuits.
	The cet cet cet Currents in any one circuit do not affect the "earth" reference of any other.
	do not affect the "earth"
	reference of any other.
	preferred connection for
	circuits that require
	common "ground".
	(at "low-eg audio - frequencies)
	The above situation is one of the simplest that can occur.
	Many other more complex situations arise, but won't be
	covered here because its not really "fields + waves" material.
	Refer to the book by Ott if interested.

Near Field EMI Reduction - Minimising capacitive coupling



(A) NEAR FIELD In this case we can consider the effect of	
electric and magnetic fields separately. In fact,	
circuit theory can be used to model the electric	
and magnetic interactions involved.	
The most common interference problems encountered (especially	
within a piece of equipment) are due to near field coupling.	
eg at 1MHz, the near field extends 50m from the source.	
PROBLEMS and SOLUTIONS.	
O Capacitive (electric near-field) coupling.	Shielding against electric field coupling:
1 C12/1	egs. i) coaxial cable, ii) guard ring on circuit boords, etc.
Vs I I Cig I R2g I C2g (or any other shaped conductors) can be calculated using methods learnt two conductors above in electrositatics.	$\begin{array}{c} c_{1s} \\ c_{3} \pm \\ c_{3} \pm \\ c_{2} \pm \\ c_{3} \pm \\ $
a ground plane. eg for two parallel wires C & 27.8 Er [pF/n] (2h - distance between conductors) (2h/a)	
	If the shield is grounded, and concluctor 2 is kept
Grz (a: tadius of conductors)	totally within the shield then all electric field
$V \odot = \frac{1}{160} c = \frac{1}{2} R_{23}$	coupling between conductors 1 and 2 is eliminated.
if $R_{2g} \ll Z_{c12} Z_{c2g}$ then $V_2 = j \omega R_{c12} V_s$	(Note: there is no such thing as a perfect ground or perfect
so clearly pickup on conductor 2 is	shield in practice, but they can be made pretty good, with care)
proportional to frequency, impedance to ground,	
capacitance from source, strength of source	
Solutions: is lower impedance wrt earth of "receiver"	
ii) reduce capacitive couplingroves wires opart	
Tii) increase Cig, Cig - keep wires close to ground plane	

Near Field EMI Reduction - Minimising inductive coupling



(2) Inductive (magnetic near field) coupling.
Vi D Rai 2 Raz The mutual inductance between two marks I loops carrying low frequency currents can be calculated using methods I Raz learned in magnetostatics.
$V_{2} = j w M I_{1}$ $V_{2} = j w M I_{1}$ $Solution: reduce M = \mu \oint \int dI_{1} \cdot dI_{2}$ $\frac{1}{4\pi} C_{1} C_{2} \frac{1}{ T_{1} - T_{2} }$ $R_{1} = R_{2}$ $ie reduce magnetic flux linkages between -fhe two circuits.$
- Increase distance between circuits - decrease area enclosed by each circuit. Spreadth eg * twisted pairs of wire * use shield for return current path edg arready Note: grounding at both ends can cause problems at audio frequencies because of "earth loops" - noise current can flow in shield, and this couples to the centre conductor.

Far Field EMI Reduction - Minimising radiative coupling



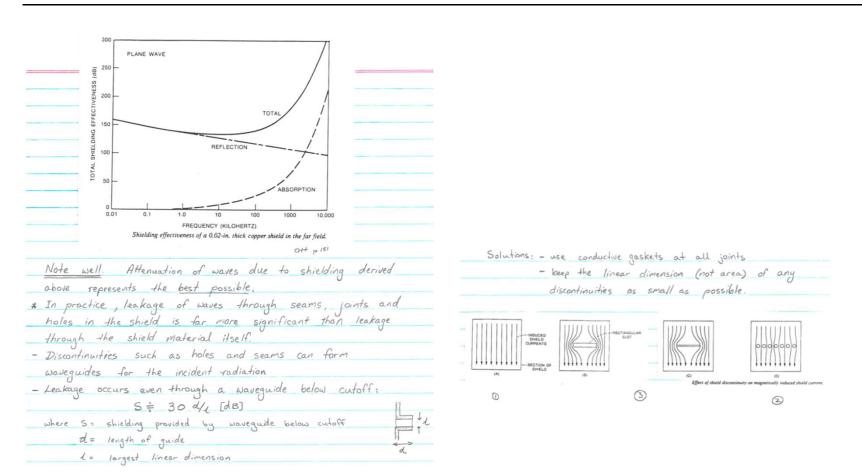
In this case the electric and magnetic fields are considered together (is alleborganetic waves). are considered together (is alleborganetic waves). where a wave may be converted to vallages and currents in the cave may be converted to vallages and currents in the cave may be converted to vallages and currents are mained, second to a decame, workges and currents are induced, second in that case its usually desirable). The nod effective method of reducing mained interference is chiefding. Shelding effectiveness varies with flequency, geometry of shield, direction of incidence and palarisation of the incident wave, while ensider a plane shield and is effected to while ensider a plane shield and part of what remains is creflected at the second boundary of $z = 100 \text{ main is in the conductor}$ is plane wave strikes a plane conducting sheet, when a plane wave strikes a plane conducting sheet, when a plane wave strikes a plane conducting sheet, when a plane wave strikes a plane conductor and is when a plane wave strikes (is absorption occurs when a plane wave striked in the conductor ond is when a plane wave strikes (is absorption occurs when a plane wave striked in the third wave and is effectiveness is settime. The shield where A = absorption loss (dws) where A = absorption loss	B FAR FIELD	Reflection loss
are considered together (i.e. electromagnetic waves). is then a wave encounters on electronic circuit, some of the energy in the cover radio anterna, workges and currents in the circuit which gually are not charted. (eq when a wave encounters a TV or radio anterna, workges and currents are induced, encept in that case its usually desirable). The most effective method of reducing radiated interference is shielding. Shielding effectiveness, works with frequency, geometry of shield, direction of incidence and polarisation of the incident wave. Will consider a plane sources when a plane wave. when a plane wave. when a plane wave. when a plane wave. when a plane to the conducting sheet, is effect on a plane wave. when a plane to fund the conducting sheet. is afficied on its transmited into the conducting sheet. is afficied on its is reflected at the second boundary (and is further disposed by conductor) is part is transmited past the shield is a first boundary. is a conductive retirem discuss. Second boundary (and is further disposed by conductor) is part is transmited past the shield		
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$\frac{c}{w_{1}} = \frac{c}{w_{1}} = $		der anducter lalt [1] and a 277 507 [dB]
$\frac{c}{w_{1}} = \frac{c}{w_{1}} = $	10 part is transmitted into the conductor and is	por conduction 1/5 - what sel, and 1/0 = 31.1 (sel) Asides
$\frac{E_{1}}{H_{1}}$ iv) part is transmitted past the shield. $\frac{E_{1}}{H_{1}}$ $\frac{E_{1}}{H_{1}}$ $\frac{E_{1}}{H$	« attenuated as it travels (ie absorption occurs	
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Total shielding effectiveness is S = A + R + B [dB] where $A = absorption loss [dB]$ $R = reflection loss [dB]$ $R = controlion loss [dB]$ $Correction for thin shields$		Hosorption 1055
Total shielding effectiveness is S = A + R + B [dB] where $A = absorption loss$ [dB] R = reflection loss [dB] R = controlion loss [dB] R = controlion loss [dB] R = reflection loss [dB] R = controlion loss [dB]	(iv) part is transmitted past the shield.	H wave propagating in a conductive medium decreases PE large
where A = absorption loss [dB] R = reflection loss [dB] R = controlion loss [dB] R = controli		
where A = absorption loss [dB] R = reflection loss [dB] R = controlion loss [dB] R = controli		where $\alpha = \perp = \lfloor \omega \mu \sigma' \\ 2 \\ \qquad \qquad$
R = reflection loss [dB] (where d = thickness of shield) R = controlion for thin shields	S = A + R + B [dB]	
B = convolion factor for multiple pollections [de] Correction for this shields	where A = absorption loss [dB]	00 H= 20 log (e. 0) = 8.69 (a/s) [dB] (ie ~ 9dB per skin depl
$B = \text{ correction factor for multiple reflections [dB]} \qquad \underbrace{\text{Correction for thin shields}}_{\text{in shields less than about one skin depth thick.}} \qquad B = 20 \log \left(1 - e^{-d/s}\right) [dB] \qquad \underbrace{\text{(neglects phase shifts)}}_{\text{in shield since } d\ll\lambda}$		
in shields less than about one skin depth thick. $B = 20 \log (1 - e^{-7}) [dB]$ (neglects phase shifts in shield since $d \ll \lambda$)	B = correction factor for multiple reflections [dB]	Correction for thin shields
	in shields less than about one skin depth thick.	$B = 20 \log (1 - e^{78}) [dB] (neglects \ phase \ shifts \ in \ shield \ since \ d \ll \lambda)$

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This correction is usually not required except at low frequencies or in perfect conductors or very thin films.

Far Field EMI Reduction - Minimising radiative coupling





Reduce EMI coupling



Additional material to be included

Methods – physical (layout), electrical (impedance mismatch)

- common and differential mode EMI
- conducted EMI filtering
- radiated EMI

antennas, shielding, Babinet's principle, new composite materials, ventilation

EMI/EMC measurements



Additional material to be included

- **EMI/EMC** Measurements
- conducted EMI LISN
- time-frequency relationships





- Switch-mode power electronics becoming increasingly common in modern power systems → Internet of Energy.
- Component advances enabling faster switching (ns) at higher frequencies (harmonics to GHz) → efficient, compact converters.
- Broadband EMI noise an increasing problem, especially for low power wireless communications and the Internet of Things.
- Power spectral density of generated EMI can be reduced using a choice of PWM and switching methods.
- Various EM coupling mechanisms (conducted, induced, radiated)
 - dominant mode of interference depends on frequency, distance from source
 - coupling can be minimized by impedance mismatch (filters, shielding, etc).
- EMI may be minimized by careful design, based on understanding of fundamentals of EMI generation and coupling.



Note: The following list of resources is not exhaustive....

BOOKS

- André and Wyatt, EMI Troubleshooting Cookbook for Product Designers, Scitech Publishing, 2014.
- Costa, Gautier, Laboure, & Revol, Electromagnetic Compatibility in Power Electronics, Wiley, 2014.
- Duff, Designing Electronic Systems for EMC, SciTech Publishing, 2011.
- Gonschorek & Vick, Electromagnetic Compatibility for Device Design and System Integration, Springer, 2009
- Montrose, EMC and the Printed Circuit Board: Design, Theory, and Layout Made Simple, Wiley-IEEE Press, 1998.
- Montrose, Nakauchi, Testing for EMC Compliance: Approaches and Techniques, Wiley-IEEE Press, 2004.
- Morgan, A Handbook for EMC Testing and Measurement (IET Electrical Measurement Series), IET, 1994.
- Paul, Introduction to Electromagnetic Compatibility, Wiley Interscience, 2006.
- * Plonus, Applied Electromagnetics, McGraw-Hill, 1978.
- Ott, Noise Reduction Techniques in Electronic Systems, Wiley Interscience, 1976 & 1988.
- * Ott, Electromagnetic Compatibility Engineering, Wiley Interscience, 2009.
- Weston, Electromagnetic Compatibility: Principles and Applications, CRC Press, 2001.
- Williams and Jost, EMC For Product Designers, Newnes, 2017.
- Wyatt, EMC Pocket Guide, SciTech Publishing, 2013.

TECHNICAL ARTICLES AND JOURNAL PAPERS

- Armstrong, Fundamentals of EMC Design, Interference Technology, 2012. http://www.interferencetechnology.com/wp-content/uploads/2012/04/Armstrong_DDG12.pdf
- Ganesan & Kini, Electromagnetic Interference/Compatibility (EMI/EMC) Measurement, IETE Technical Review, 20(5), p415, 2003.
- Kopke, et al, Complexities of Testing Interference and Coexistence of Wireless Systems in Critical Infrastructure, NIST TN.1885, 2015. http://nvlpubs.nist.gov/nistpubs/TechnicalNotes/NIST.TN.1885.pdf
- Mediano, EMI/EMC troubleshooting techniques in switching mode power supplies, European Conf. Power Electronics, 2009.
- Raza, et al, Low Power Wide Area Networks: An Overview, IEEE Communications Surveys & Tutorials, 19(2), p855, 2017. <u>https://arxiv.org/pdf/1606.07360.pdf</u>
- Shalaby, et al, Evaluation of Electromagnetic Interference in Wireless Broadband Systems, Wireless Personal Communications 96(2), p2223, 2017.
- Shapira, Electromagnetic Compatibility for System Engineers, IETE Technical Review, 28(1), p70, 2011.



APEC AND OTHER PRESENTATIONS

- Colotti, EMC Design Fundamentals, <u>https://www.ieee.li/pdf/viewgraphs/emc_design_fundamentals.pdf</u>
- Ott, Understanding and controlling common-mode-emissions in high-power electronics, APEC 2002.
 <u>http://www.hottconsultants.com/pdf_files/APEC-2002.pdf</u>
- Schutten, "EMI Causes, Measurement, and Reduction Techniques for Switch-Mode Power Converters", APEC2017 Professional Education seminar.
- Ray, "Introduction to EMC", APEC2017 Professional Education Seminar.

PROFESSIONAL SOCIETIES AND PUBLICATIONS

- IEEE EMC Society, <u>http://www.emcs.org/</u>
- IEEE Transactions on Electromagnetic Compatibility, <u>http://ieeexplore.ieee.org/xpl/RecentIssue.jsp?punumber=15</u>
- IEEE Electromagnetic Compatibility Magazine, http://ieeexplore.ieee.org/xpl/RecentIssue.jsp?punumber=5962381
- IET Electromagnetics Network, <u>https://communities.theiet.org/communities/home/57</u>
- IET, EMC for functional safety, <u>https://www.theiet.org/factfiles/emc/index.cfm</u>?

STANDARDS AND REGULATORY ORGANISATION WEBPAGES AND PUBLICATIONS

- ANSI, Standards Committee C63 EMC, <u>http://www.c63.org/index.htm</u>
- DOE, 10 CFR Part 430 Energy Conservation Program: Energy Conservation Standards for External Power Supplies; Final Rule, 2014.
 <u>https://www.regulations.gov/document?D=EERE-2008-BT-STD-0005-0219</u>
 <u>https://www.regulations.gov/contentStreamer?documentId=EERE-2008-BT-STD-0005-0219&contentType=pdf</u>
- ETSI, EMC webpages, <u>http://www.etsi.org/technologies-clusters/technologies/emc</u>
- European Commission, Electromagnetic Compatibility (EMC) Directive, http://ec.europa.eu/growth/sectors/electrical-engineering/emc-directive_en
- FCC, Federal Regulations Title 47 (Telecommunication) Part 15 (Radio Frequency Devices), https://www.fcc.gov/wireless/bureau-divisions/technologies-systems-and-innovation-division/rules-regulations-title-47 https://www.gpo.gov/fdsys/pkg/CFR-2015-title47-vol1/pdf/CFR-2015-title47-vol1-part15.pdf
- FDA, FDA/CDRH Recommendations for EMC/EMI in Healthcare Facilities
 https://www.fda.gov/Radiation-EmittingProducts/RadiationSafety/ElectromagneticCompatibilityEMC/ucm116566.htm
- IEC/CISPR, Electromagnetic compatibility and the IEC, <u>http://www.iec.ch/emc/</u>
- IEC/CISPR, Structure of CISPR 16, <u>http://www.iec.ch/emc/basic_emc/basic_cispr16.htm</u>
- IEC, Structure of IEC 61000, <u>http://www.iec.ch/emc/basic_emc/basic_61000.htm</u>
- IEC, Smart Grid and EMC, <u>http://www.iec.ch/emc/smartgrid/</u>
- ISO, 33.100 Electromagnetic compatibility (EMC), <u>https://www.iso.org/ics/33.100/x/</u>
- US Department of Defense, MIL-STD-461G December 2015, REQUIREMENTS FOR THE CONTROL OF ELECTROMAGNETIC INTERFERENCE CHARACTERISTICS OF SUBSYSTEMS AND EQUIPMENT http://quicksearch.dla.mil/Transient/EB9A010D027843DCA4472B5850B6B39F.pdf



OTHER RESOURCES AND VARIOUS WEB LINKS

- <u>https://en.wikipedia.org/wiki/Electromagnetic_interference</u>
- https://en.wikipedia.org/wiki/Electromagnetic compatibility
- · https://en.wikipedia.org/wiki/List of common EMC test standards
- http://www.electrical-installation.org/enwiki/ElectroMagnetic Compatibility (EMC)
- https://en.wikipedia.org/wiki/Modulation
- · https://en.wikipedia.org/wiki/Orthogonal frequency-division multiplexing
- <u>https://en.wikipedia.org/wiki/Radio_spectrum</u>
- <u>https://en.wikipedia.org/wiki/ISM_band</u>
- https://en.wikipedia.org/wiki/LPWAN
- https://en.wikipedia.org/wiki/NarrowBand_IOT
- Analog Devices, EMI, RFI, and Shielding Concepts, Tutorial MT-095, 2009. http://www.analog.com/media/en/training-seminars/tutorials/MT-095.pdf
- Armstrong, Checklist of Good EM Engineering Practices, 2012. https://www.emcstandards.co.uk/files/checklist_of_good_em_engineering_practices_keith_armstrong_2012.docx
- Beginner's Guide To EMC, <u>https://www.emcfastpass.com/emc-testing-beginners-guide/</u>
- Copper Development Association, Power Quality and Utilisation Guide, http://copperalliance.org.uk/resource-library/power-quality-and-utilisation-guide
- Corsaro, et al (STMicrolectronics), EMC design guides for motor control applications, AN4694, 2015. http://www.st.com/content/ccc/resource/technical/document/application_note/f7/f4/51/8d/a1/c5/47/8e/DM00182773.pdf// http://www.st.com/content/ccc/resource/technical/document/application_note/f7/f4/51/8d/a1/c5/47/8e/DM00182773.pdf// http://www.st.com/content/ccc/resource/technical/document/application_note/f7/f4/51/8d/a1/c5/47/8e/DM00182773.pdf// http://www.st.com/content/ccc/resource/technical/document/application_note/f7/f4/51/8d/a1/c5/47/8e/DM00182773.pdf
- CUI Inc., EMI considerations for switching power supplies, 2013. http://www.cui.com/catalog/resource/emi-considerations-for-switching-power-supplies.pdf
- CUI Inc., Efficiency Standards for External Power Supplies, 2018. http://www.cui.com/catalog/resource/efficiency-standards-for-external-power-supplies.pdf
- CVEL (Clemson University Vehicular Electronics Laboratory), Electromagnetic Compatibility Resources, https://cecas.clemson.edu/cvel/emc/
- Delaballe, Cahier technique no. 149 EMC: electromagnetic compatibility, http://eduscol.education.fr/sti/sites/eduscol.education.fr.sti/files/ressources/techniques/3398/3398-ect149.pdf
- Ericsson, Cellular networks for massive IoT, White paper Uen 284 23-3278, January 2016. https://www.ericsson.com/assets/local/publications/white-papers/wp_iot.pdf
- Frenzel, Understanding Modern Digital Modulation Techniques, Electronic Design, Electronic Design, Jan. 2012.
 http://www.electronicdesign.com/communications/understanding-modern-digital-modulation-techniques
- Gluhak, Low Power Wide Area Networks: The new backbone for the Internet of Things, IET 2018. https://www.theiet.org/sectors/information-communications/topics/ubiquitous-computing/articles/lpwan.cfm?



OTHER RESOURCES – VARIOUS WEB LINKS (CONTINUED)

- GSMA, 3GPP Low Power Wide Area Technologies, <u>https://www.gsma.com/iot/wp-content/uploads/2016/10/3GPP-Low-Power-Wide-Area-Technologies-GSMA-White-Paper.pdf</u>
- Hesner (Fairchild), Electromagnetic Interference (EMI) in Power Supplies, 2010.
 https://www.fairchildsemi.com/technical-articles/Electromagnetic-Interference-EMI-in-Power-Supplies.pdf
- How2Power, Power Supply EMI Anthology http://www.how2power.com/pdf_view.php?url=/other/How2Power%20EMI%20Anthology.pdf
- Hegarty, The Engineer's Guide To EMI In DC-DC Converters (Parts 1 ...), How2Power, Dec. 2017... http://www.how2power.com/pdf_view.php?url=/newsletters/1712/articles/H2PToday1712_design_TexasInstruments_Part%201.pdf http://www.how2power.com/pdf_view.php?url=/newsletters/1801/articles/H2PToday1801_design_TexasInstruments_Part%202.pdf
- Interference Technology Magazine, <u>https://interferencetechnology.com/</u>
- Keebler et al, Case Studies of EMI Elimination and Ground Noise Reduction Using Ground Noise Filters, Interference Technology, 2009. https://interferencetechnology.com/case-studies-emi-filters/
- Klinger, Radio interference from LED lighting _ EMC and Regulatory Compliance, 2011 http://www.emcrules.com/2011/07/radio-interference-from-led-lighting.html
- Leach et al (NASA), Electronic systems failures and anomalies attributed to electromagnetic interference, NASA-RP-1374, 1995. https://ntrs.nasa.gov/archive/nasa/casi.ntrs.nasa.gov/19960009442.pdf
- Learn EMC Tutorial Articles, http://learnemc.com/emc-tutorials
- LED Benchmark, FAQ LED interference Issues, <u>http://www.ledbenchmark.com/faq/LED-interference-issues.html</u>
- Lethellier, EMI For Wisdom Seekers (Parts 1 ...), How2Power, Nov. 2017... http://www.how2power.com/pdf_view.php?url=/newsletters/1711/articles/H2PToday1711_design_Noizgon_Part%201.pdf http://www.how2power.com/pdf_view.php?url=/newsletters/1712/articles/H2PToday1712_design_Noizgon_Part%202.pdf http://www.how2power.com/pdf_view.php?url=/newsletters/1801/articles/H2PToday1801_design_Noizgon_Part%203.pdf
- Li, Electromagnetic Compatibility of Switching Power Supplies (Parts 1 2), Power Electronics, 2013 http://powerelectronics.com/power-electronics-systems/electromagnetic-compatibility-switching-power-supplies-part-1-definitionshttp://www.powerelectronics.com/power-electronics-systems/electromagnetic-compatibility-part-2-considerations-when-working-switching
- Murata, Noise suppression basic course, <u>https://www.murata.com/products/emc/emifil/knowhow/basic</u>
- Paul, EMC Education Manual, IEEEEMC Society, 2004. <u>www.emcs.org/committees/education/pdf/EMC%20Education%20Manual.pdf</u>
- Pillai, Modulation roundup: error rates, noise, and capacity, 2006. https://www.embedded.com/print/4017668
- Schaffner, Basics in EMC and Power Quality, 2009. http://www.fuseco.com.au/files/Basics_in_EMC_and_Power_Quality_15_1_.pdf
- Schneider, Electromagnetic Compatibility practical installation guidelines, http://www.eschneider.pl/download/10 Poradniki/EMC.pdf
- Uhlig (Siemens), EMC Design Guidelines, 2004. <u>https://cache.industry.siemens.com/dl/files/267/18162267/att_71155/v1/mm4Appl_008_EMV_Aufbaurichtlinie_V2_1_76.pdf</u>
- Tuite, Conforming with Worldwide Safety and EMC/EMI Standards, Power Electronics, 2010. http://powerelectronics.com/power-electronics-systems/conforming-worldwide-safety-and-emcemi-standards
- Wyatt, EMI Troubleshooting step-by-step, EMI Troubleshooting Step-By-Step, Interference Technology, 2017. SCHOO https://interferencetechnology.com/emi-troubleshooting-step-step/#